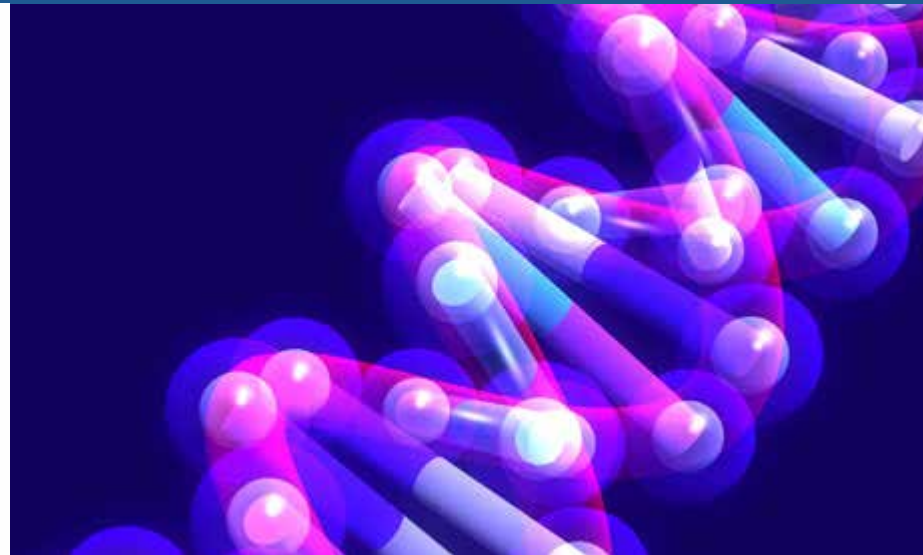


# Ultra fast electron detector – The Molecular Movie –

Sascha Epp



# EDET team

## Acknowledgements



HLL ▶ Ladislav Andricek • Martin Hensel • Christian Koffmane • Jelena Ninkovic • Gerhard Schaller • Martina Schnecke • Florian Schopper • Andreas Wassatsch • Christian Zirr

KIT ▶ Ivan Peric

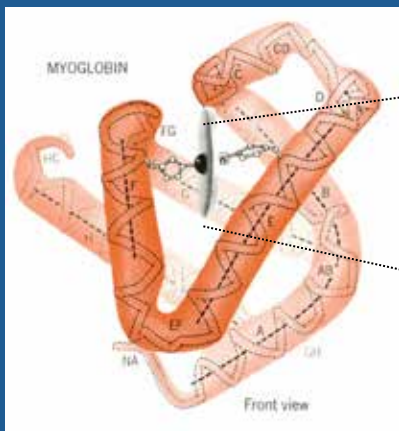
USI ▶ Klaus Gärtner

MPSD ▶ Ibrahym Dourki • Sascha Epp • R. J. Dwayne Miller • Fabian Westermeier

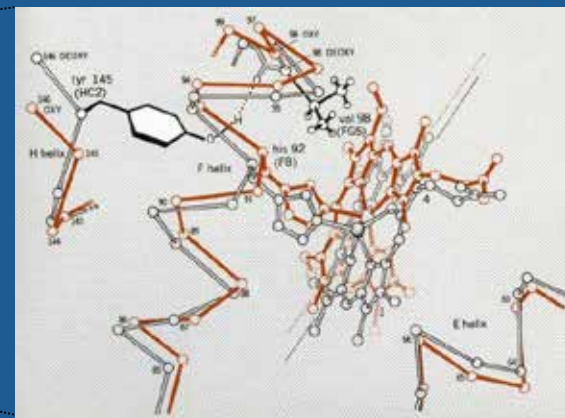


# The "Molecular Dance"

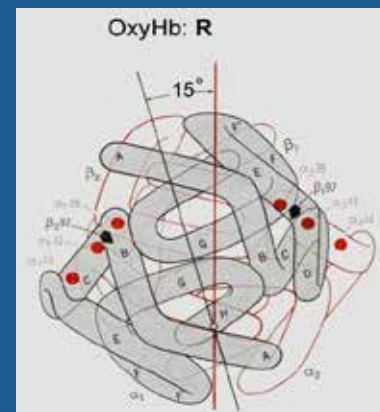
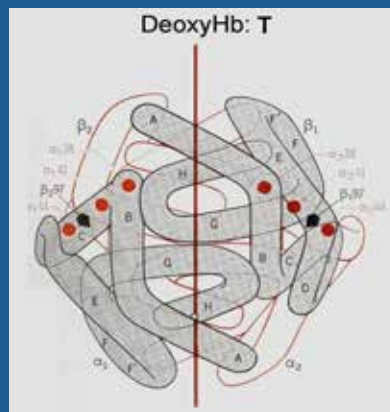
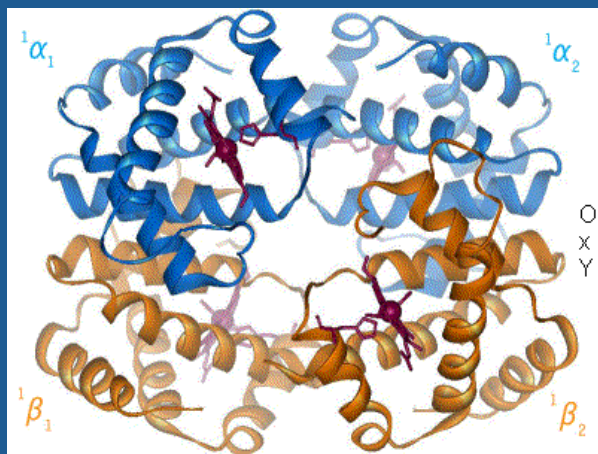
Functionally important protein motions



Myoglobin (single subunit)



Hemoglobin



What is the mechanism of correlated atomic displacements?

Structure - Function Correlation **P** resolve atomic motions on timescales faster than the onset of diffusive motions.....observe force correlations

# Experiments

Large scale



Max Planck Institute for Structure and Dynamics of Matter



European  
**XFEL**  
Hamburg

Start  
2015



at Stanford (California)



**FLASH**  
Hamburg

# Electron diffraction

The wave-particle duality of particle beams



▶ We exploit the wave nature of the electron

▶ Need to detect electrons (sig.-to-noise)

• direct-hit detector

• ~~in-direct hit detector~~



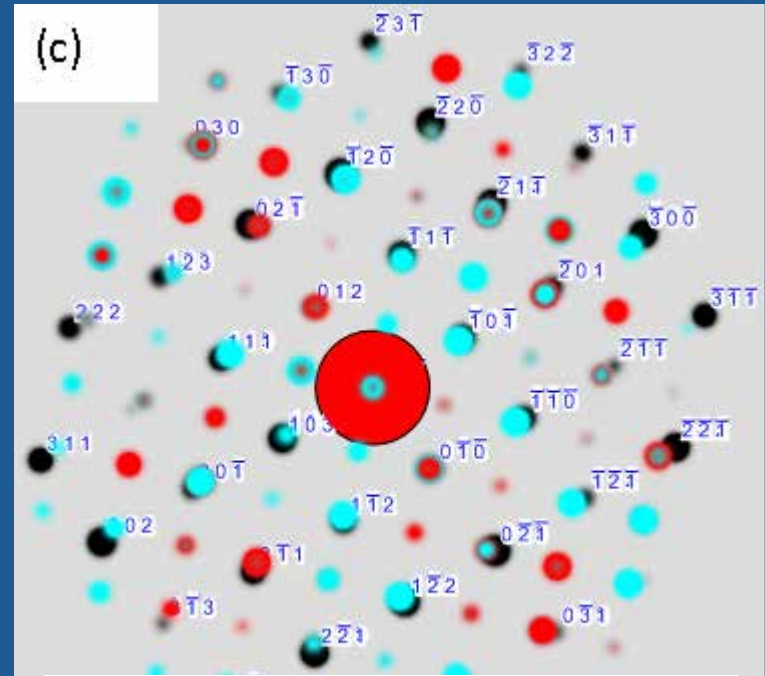
▶ scientist can do is 24/7

▶ cross section -> 1e6 times larger

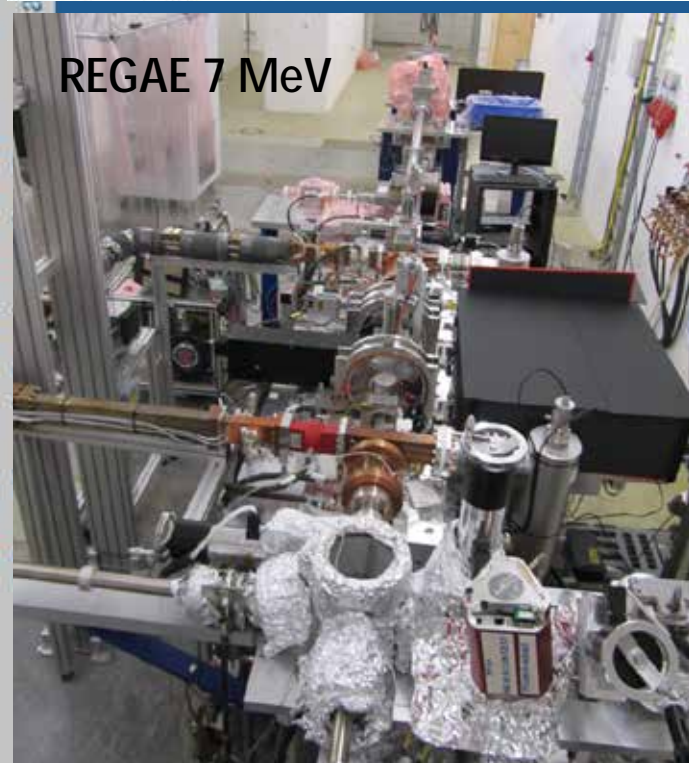
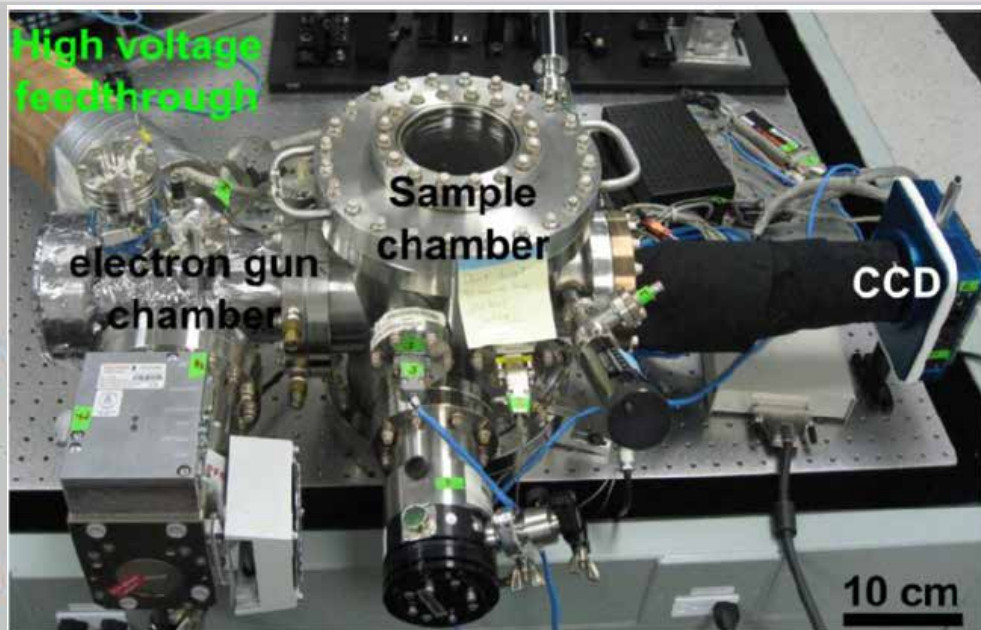
▶ mass & charge -> penetration depth

$$l_{dB} = \frac{hc}{\sqrt{2E_{kin}E_0 + E_{kin}^2}} < 0.1 \text{ \AA}$$

▶ 0.1 Å corresponds to 100 keV X-rays



**Diffraction out to less than 0.2Å!**



## *Experiments*

*Small scale & with e-*

- keV FED – solid state
- keV FED – liquid phase
- keV FED – gas phase
- REGAE Diffraction
- keV time-resolved TEM
- REGAE Dynamic RTEM



# Detector requirements



Experiment	Energy / MeV	# Pixels	Single-shot Dynamic range	Frames per second read out
REGAE relativistic electron diffraction (static & time-resolved)	3 – 5	1k x 1k (1M)	10 <sup>3</sup> (up to 10 <sup>4</sup> )	100 Hz
REGAE relativistic TEM <sup>1</sup> mode	3 – 5	2k x 2k (4M)	100	100 Hz
time-resolved TEM <sup>1</sup> (adapted commercial TEM <sup>1</sup> )	0.1 – 0.3	1k x 1k (1M)	100	ca. 1-10 MHz
keV UED <sup>2</sup> – solid state samples	0.1 - 0.3	1k x 1k (1M)	10 <sup>3</sup> (up to 10 <sup>4</sup> )	1 kHz
keV UED <sup>2</sup> – liquid phase samples	0.1 – 0.3	1k x 1k (1M)	100	1 kHz
keV UED <sup>2</sup> – gas phase samples	0.1 – 0.3	1k x 1k (1M)	>3	1 kHz

Table 1: Most demanding requirement to a detector system for the various types of experiments performed at MPSD. The most demanding requirements are indicated in red.

(<sup>1</sup>transmission electron microscope <sup>2</sup>ultrafast electron diffraction)

► Want fast detector... as reasonably possible

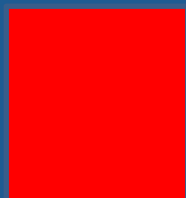
► Excellent signal to noise (single primary e- detection)

Can one single system serve all requirements?

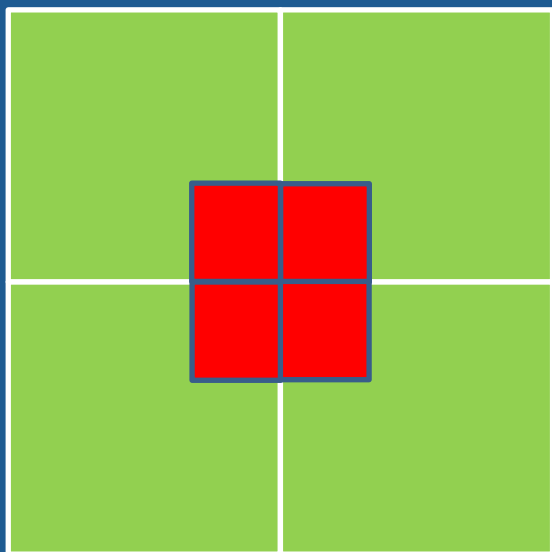
Principally yes, but we make two different (similar) systems!

# Pixel detectors

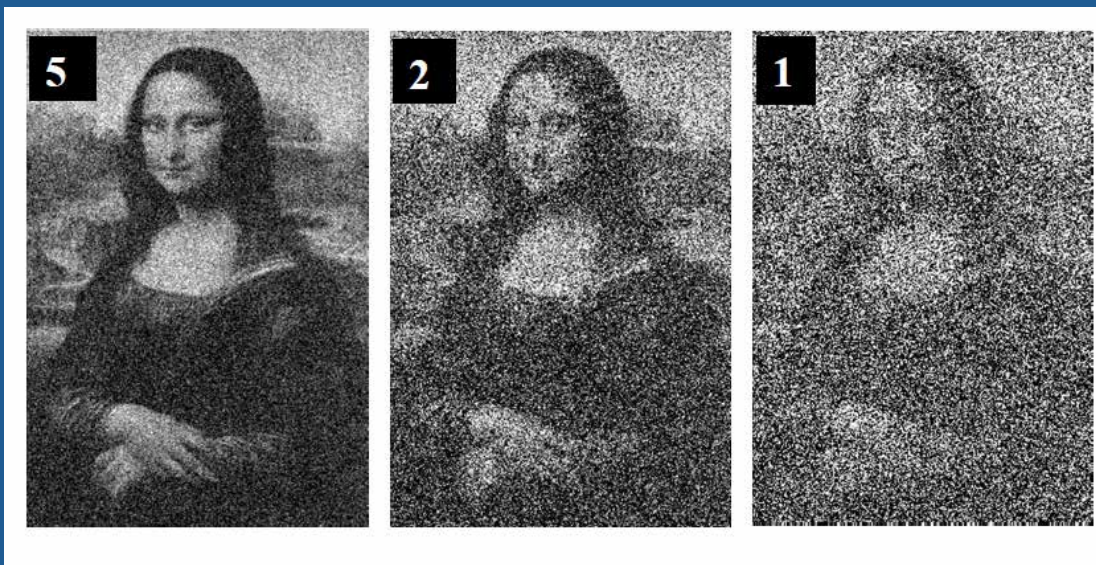
Signal to Noise (SN)



e-h pairs



4 pixel.....25% each split



For 50  $\mu\text{m}$  (110):

A fraction of  $1\text{e}(-6)$  single hit events creates less than 2700 e-h pairs

25% of 2700 is 675 e-h pairs

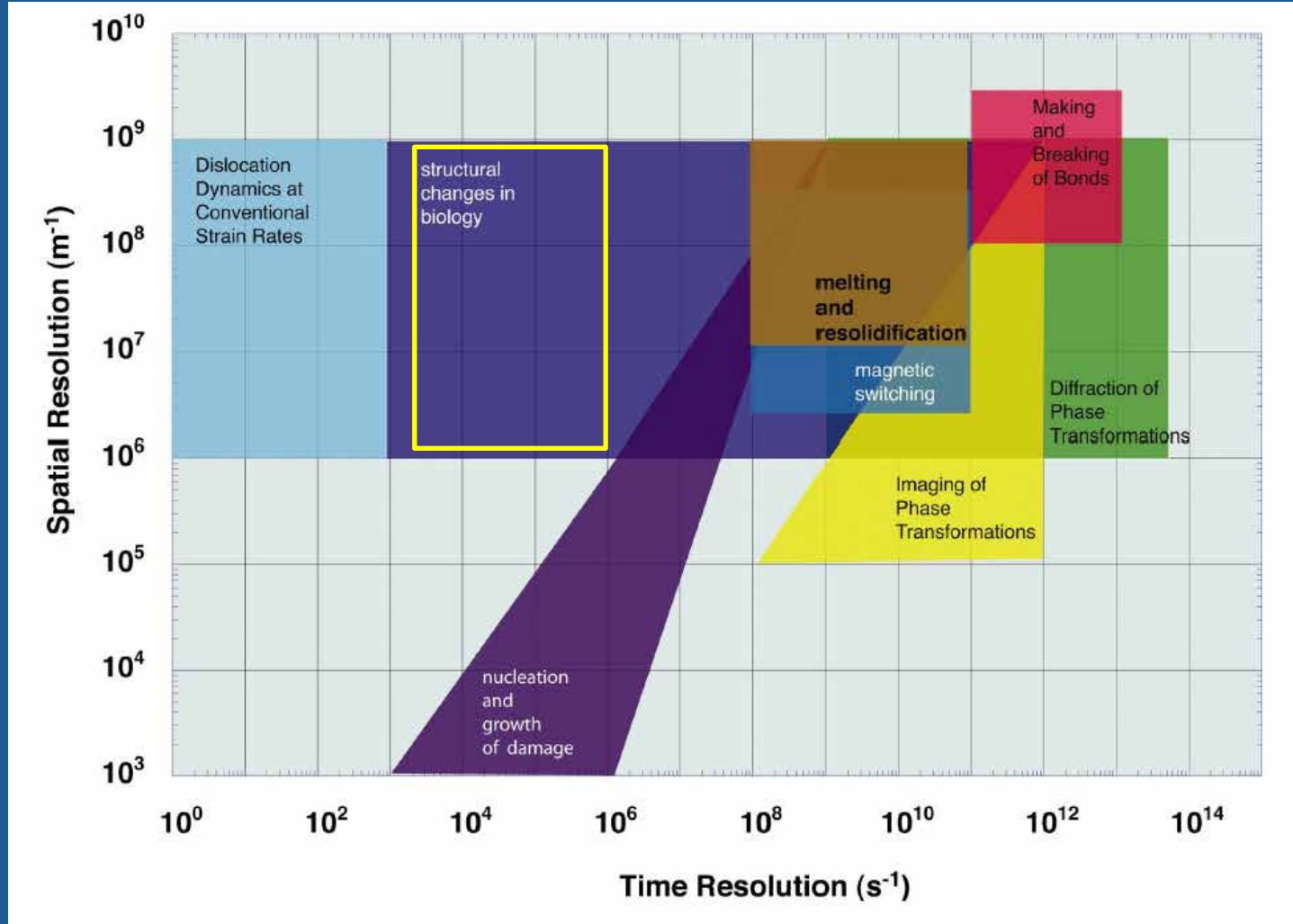
With a noise of 100 e-h pairs this is 6 sigma from noise.

Less than a fraction of  $1\text{e}(-6)$  of events has a noise of 600.



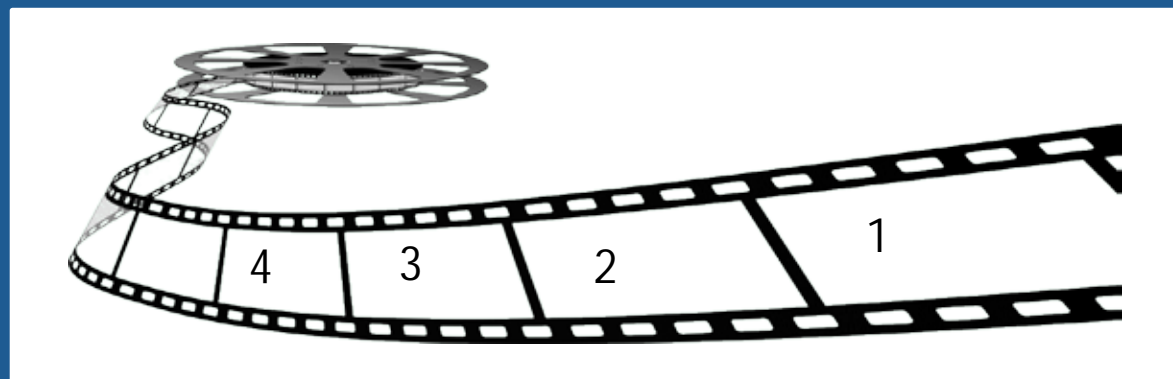
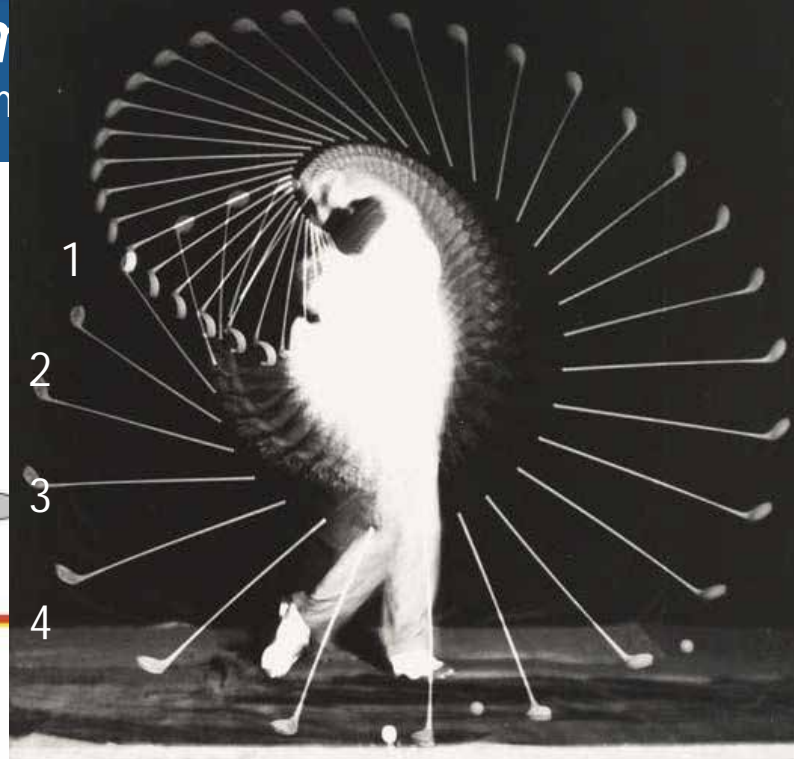
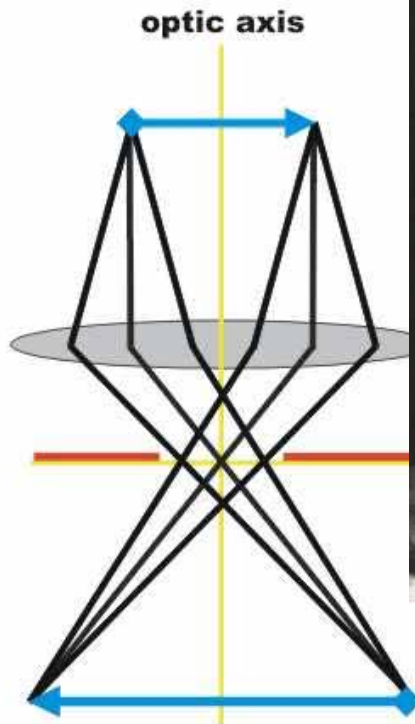
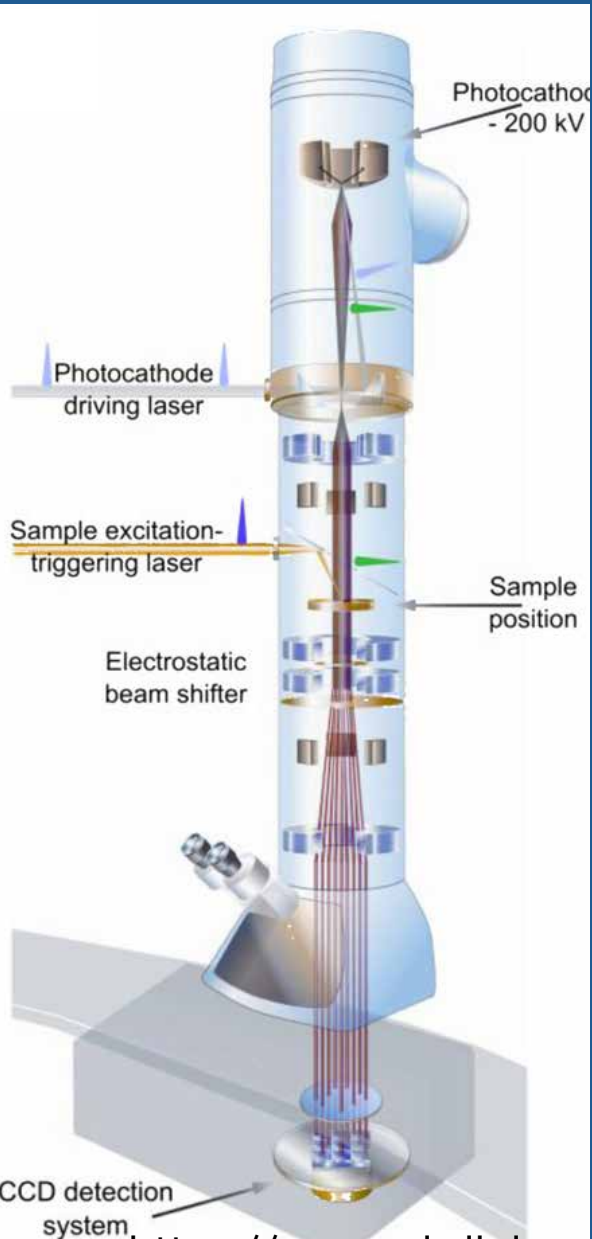
# Static & Dynamic

Time scales



# TEM real space in

A movie like in cinema

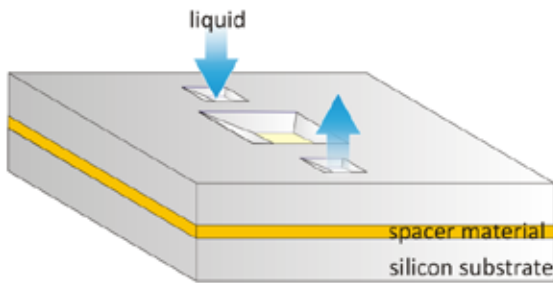


Source: <https://www-pls.llnl.gov>

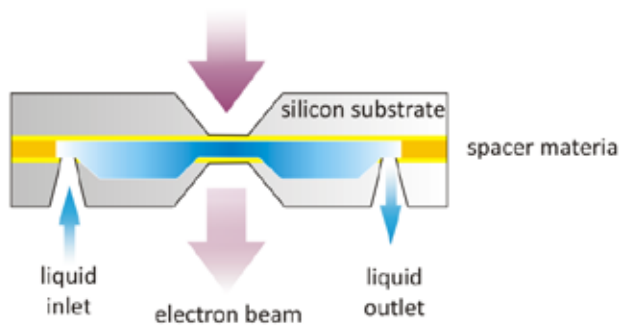
# Further Evolution in atom gazing: .....Solution Phase Dynamics

## TEM nanocell with flow!

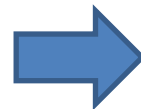
outside view



cross sectional view



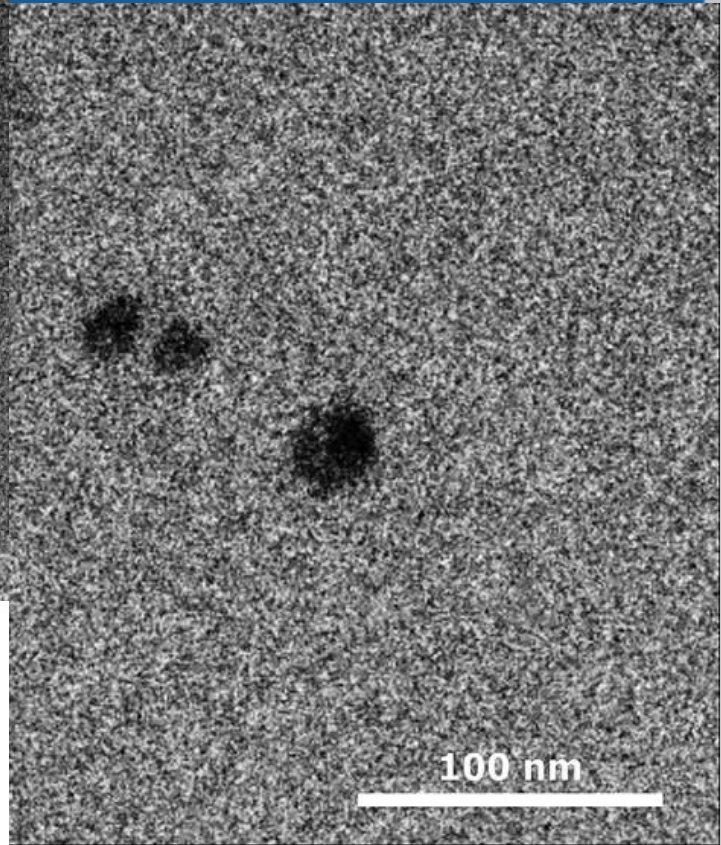
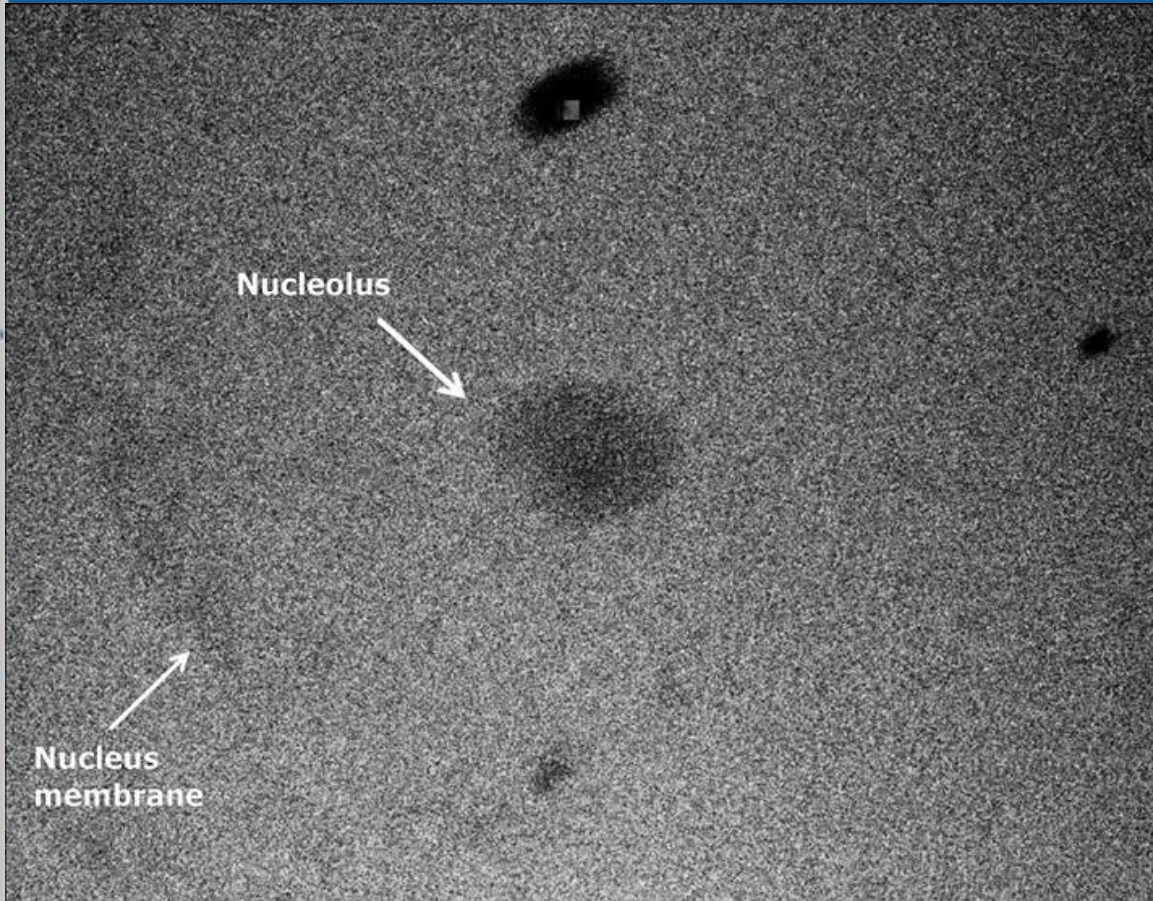
*not to scale*



Christina Müller: U Toronto  
Sercan Kescin, Stephanie Manz: MPSD

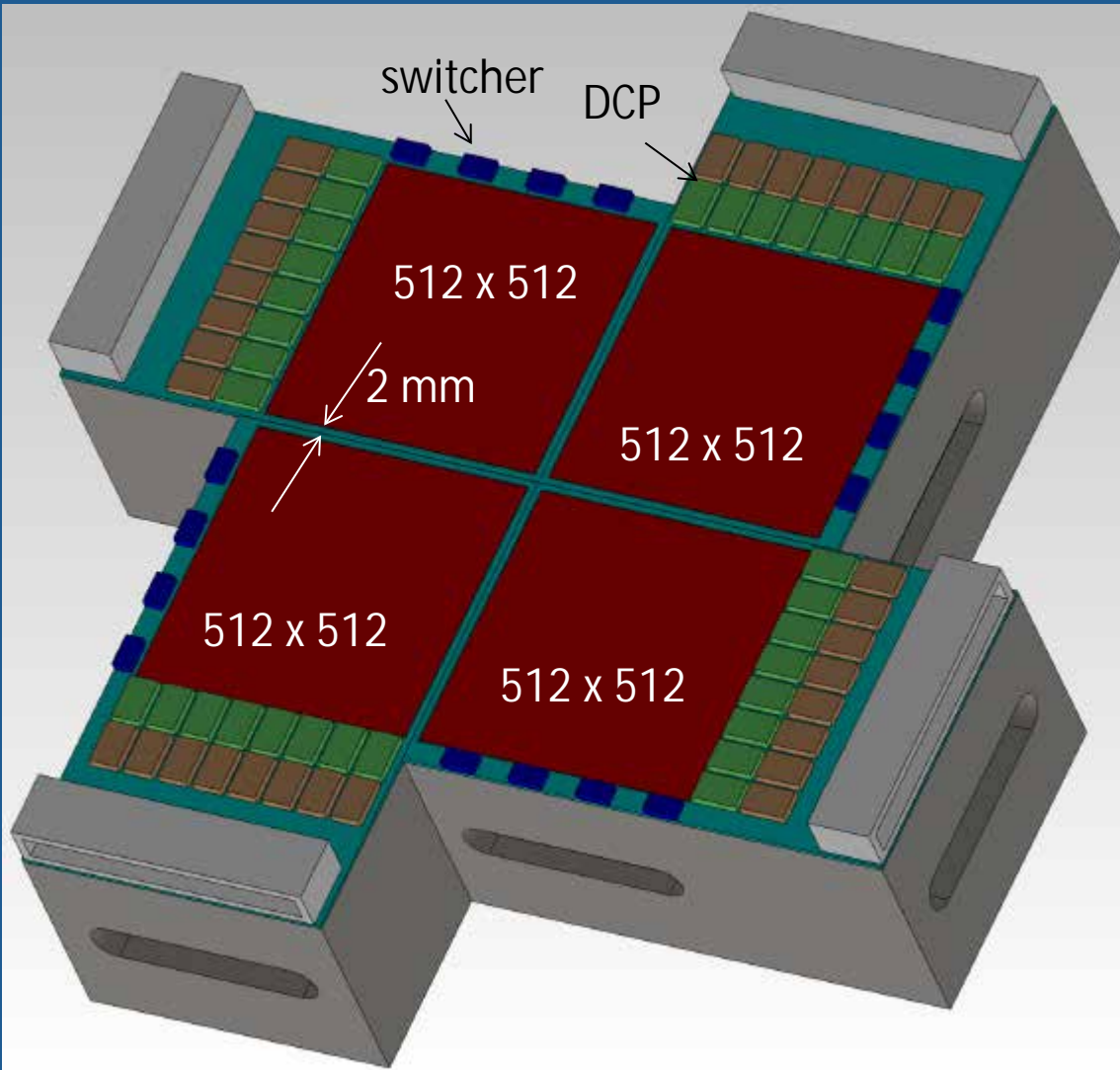
# Video

Liquid cell



# Edet system (DH80k)

DEPFET direct hit



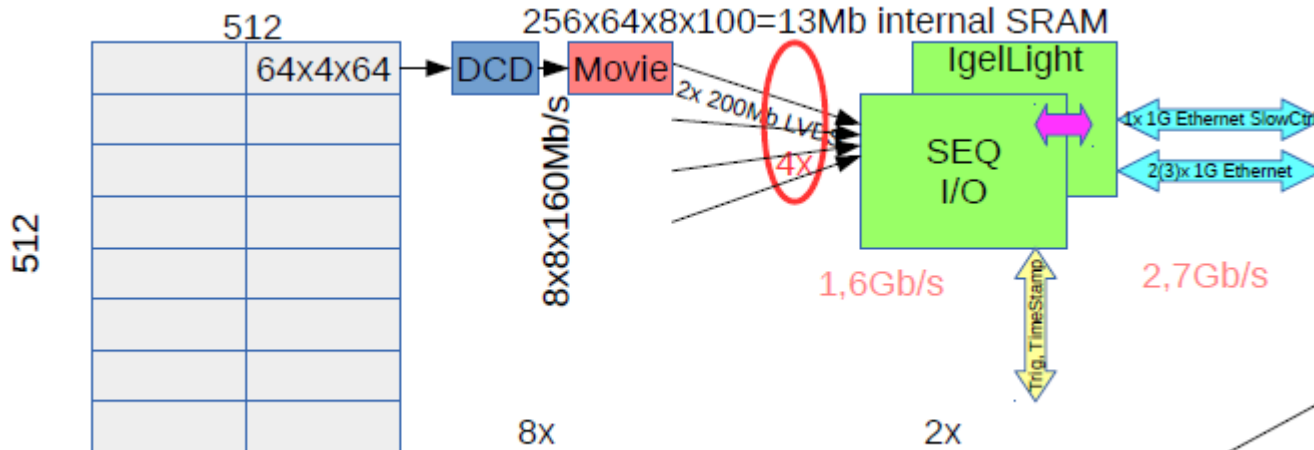
- ▶ direct electron detection
- ▶ 60 x 60 mm<sup>2</sup> active area
- ▶ 1000 x 1000 px (4 chips)
- ▶ pixel size: 60 x 60 μm<sup>2</sup>
- ▶ full frame readout 80kHz by 4-fold rolling shutter mode
- ▶ dead joining region < 2 mm



# Data stream

Use BELLE-II components where possible: How well do they fit the application

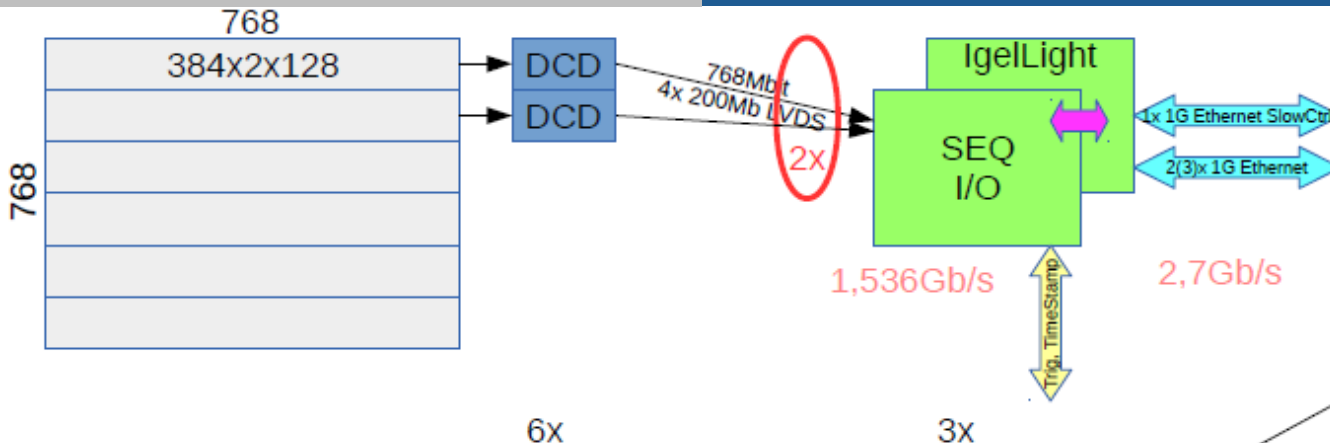
## > DH80k



▶ 80 kHz -> 80 GB/s of data if operated continuously!  
(compare DE-CIX with 230 GB/s)

▶ Solution: burst mode with movie of 100 frames.  
-> storage needed

## > DH1k



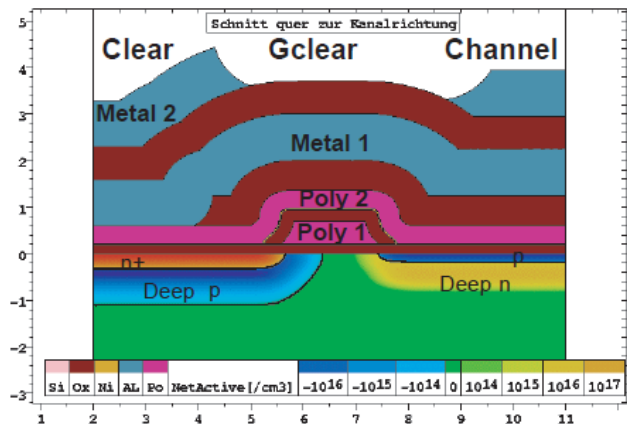
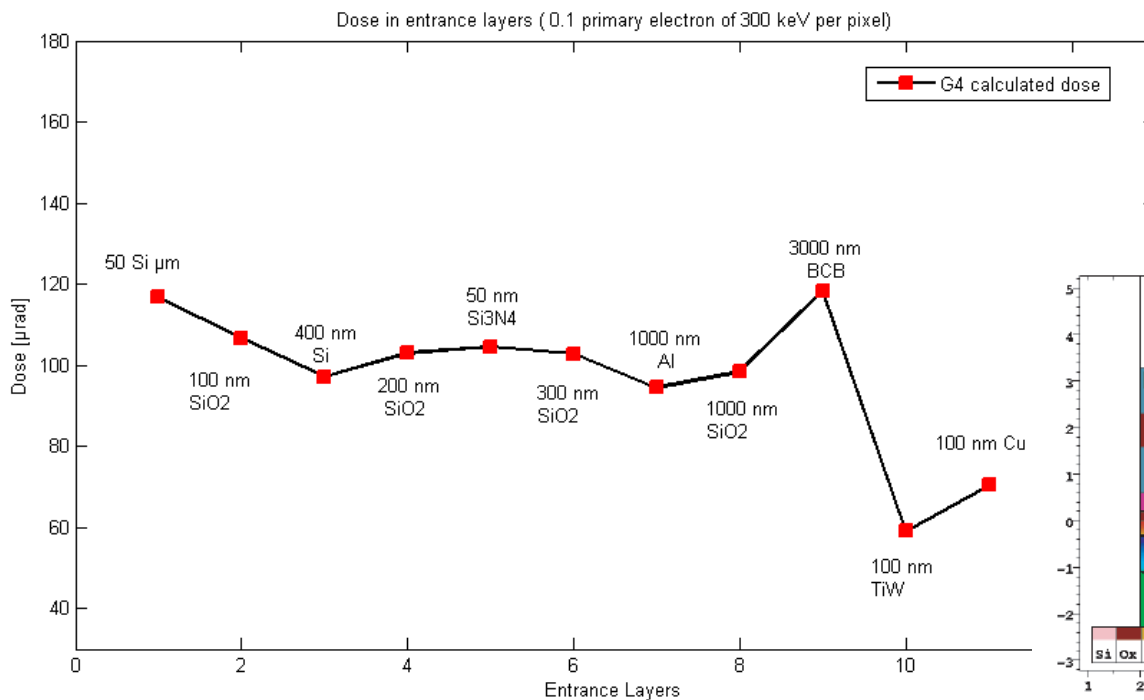
# Further main challenges



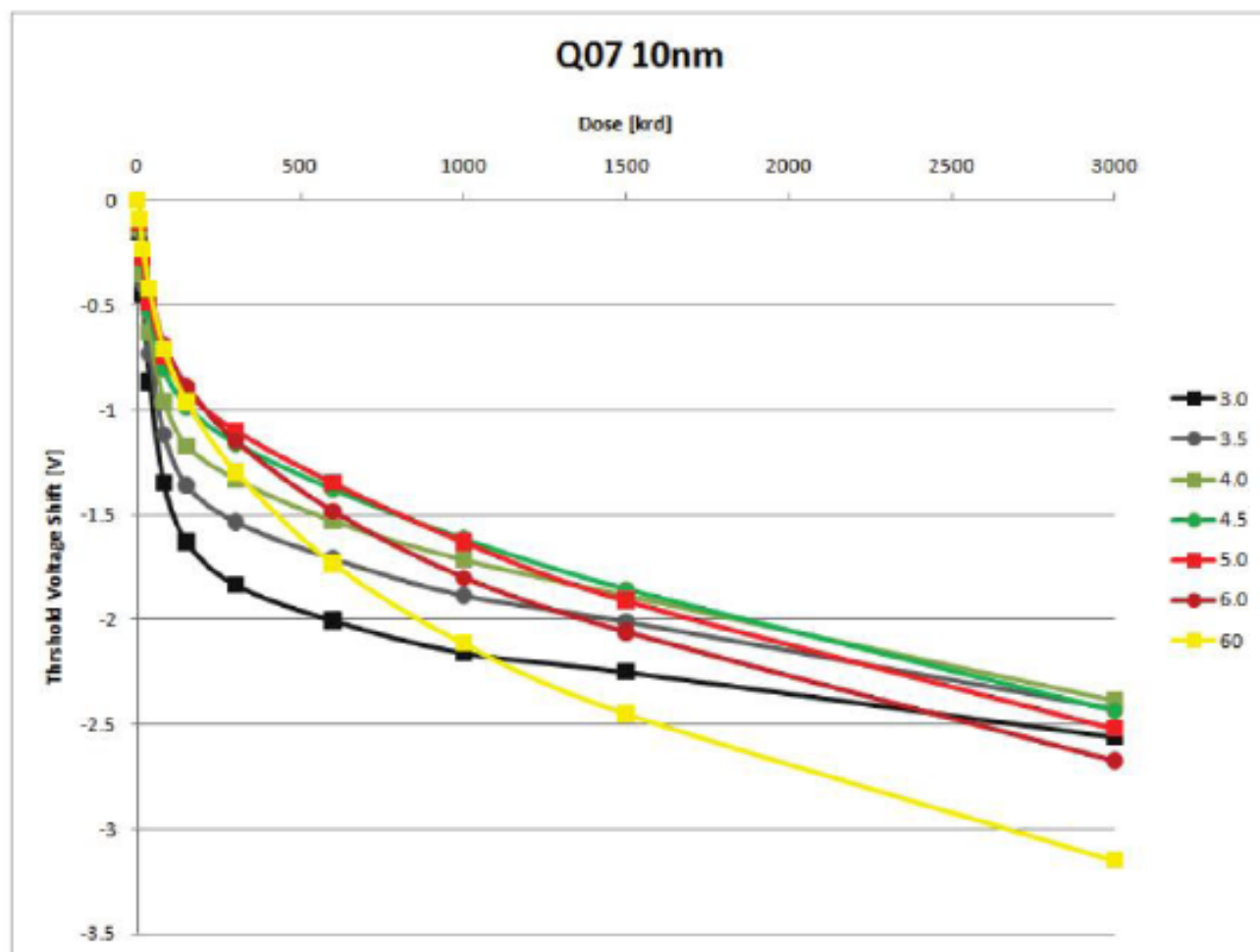
DCD resolution: Is 8 bit enough? Non linear DEPFET response (Rainer Richter) -> sufficient, more would be better.....

Radiation hardness: Suffer from radiation damage. What happens to the detector towards 10 MRad. Can we cure damage by annealing? To what extend? (Martin Hensel).

Thermal issues: due to low thermal conductivity (not solved, but doable)



# Radiation damage II – best case

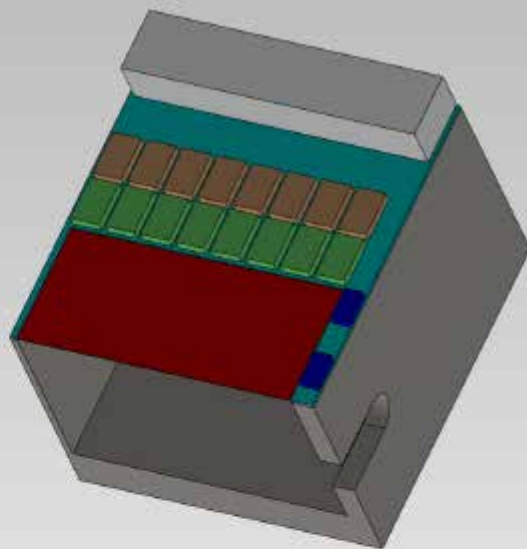


2.5V shift after 3Mrad  
almost linear increase 0.35V/Mrad (needs confirmation)



# Edet system (DH80k)

DEPFET direct hit



▶ direct electron detection

▶ 60 x 60 mm<sup>2</sup> active area

▶ 1000 x 1000 px (4 chips)

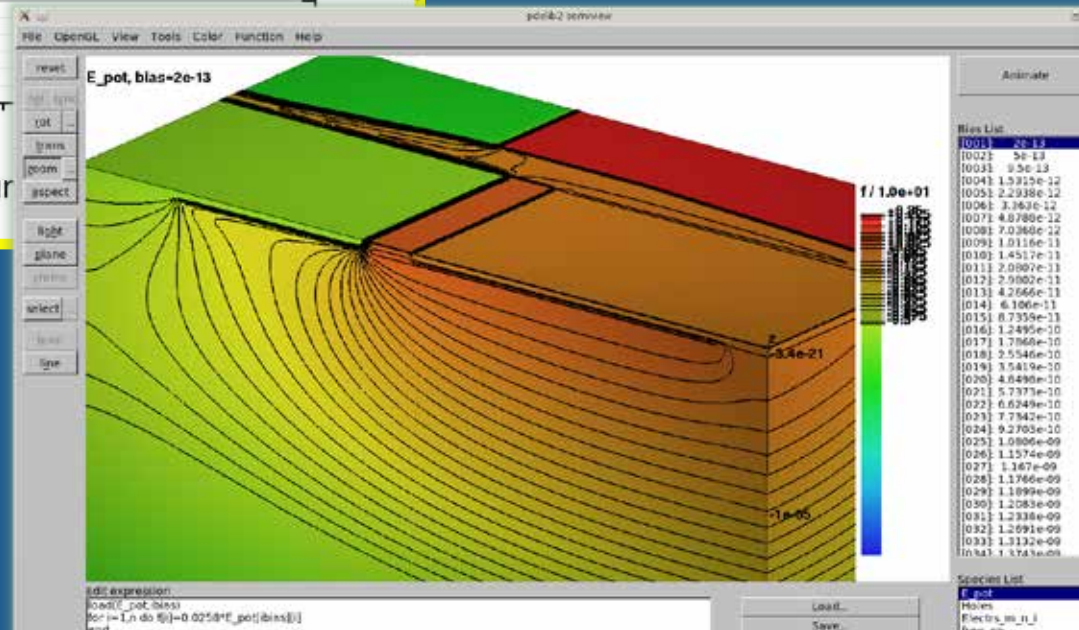
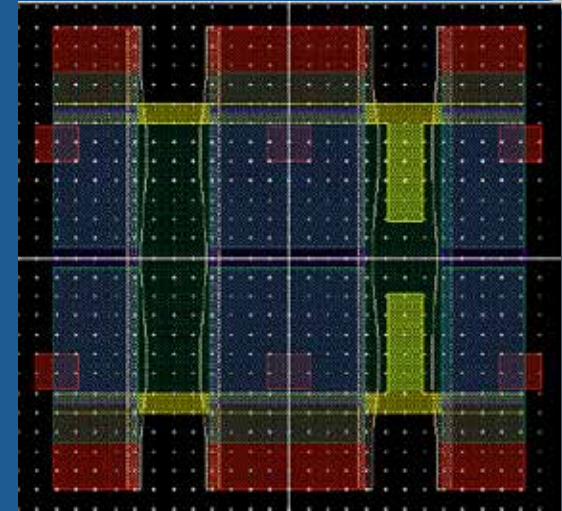
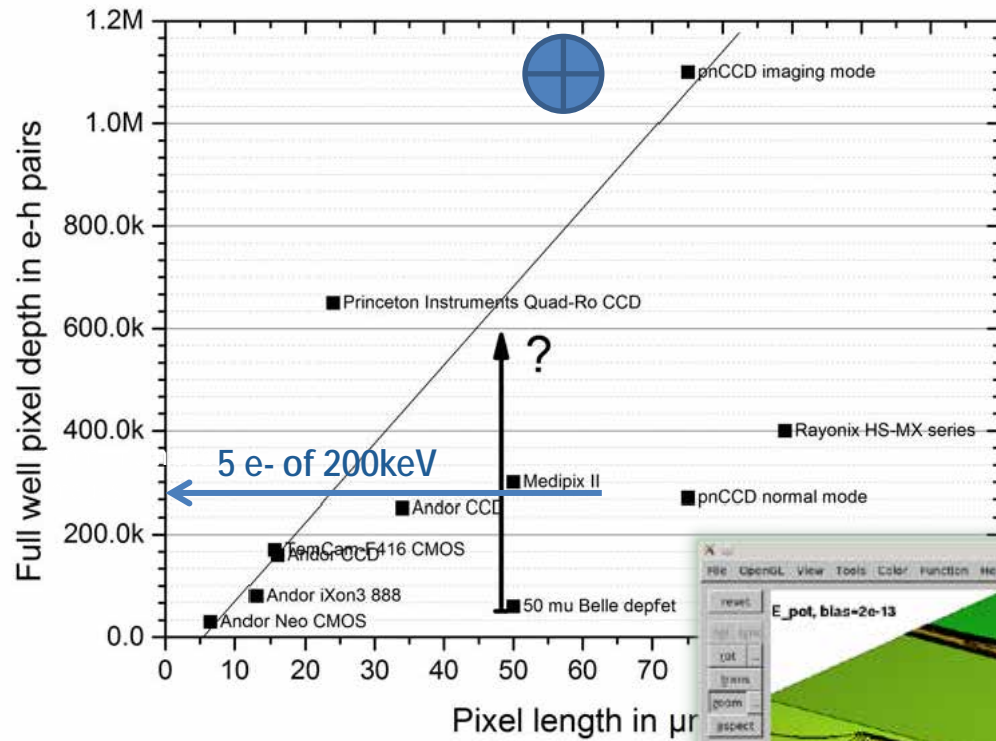
▶ pixel size: 60 x 60 μm<sup>2</sup>

▶ full frame readout 80kHz  
by 4-fold rolling shutter mode

▶ dead joining region < 2 mm

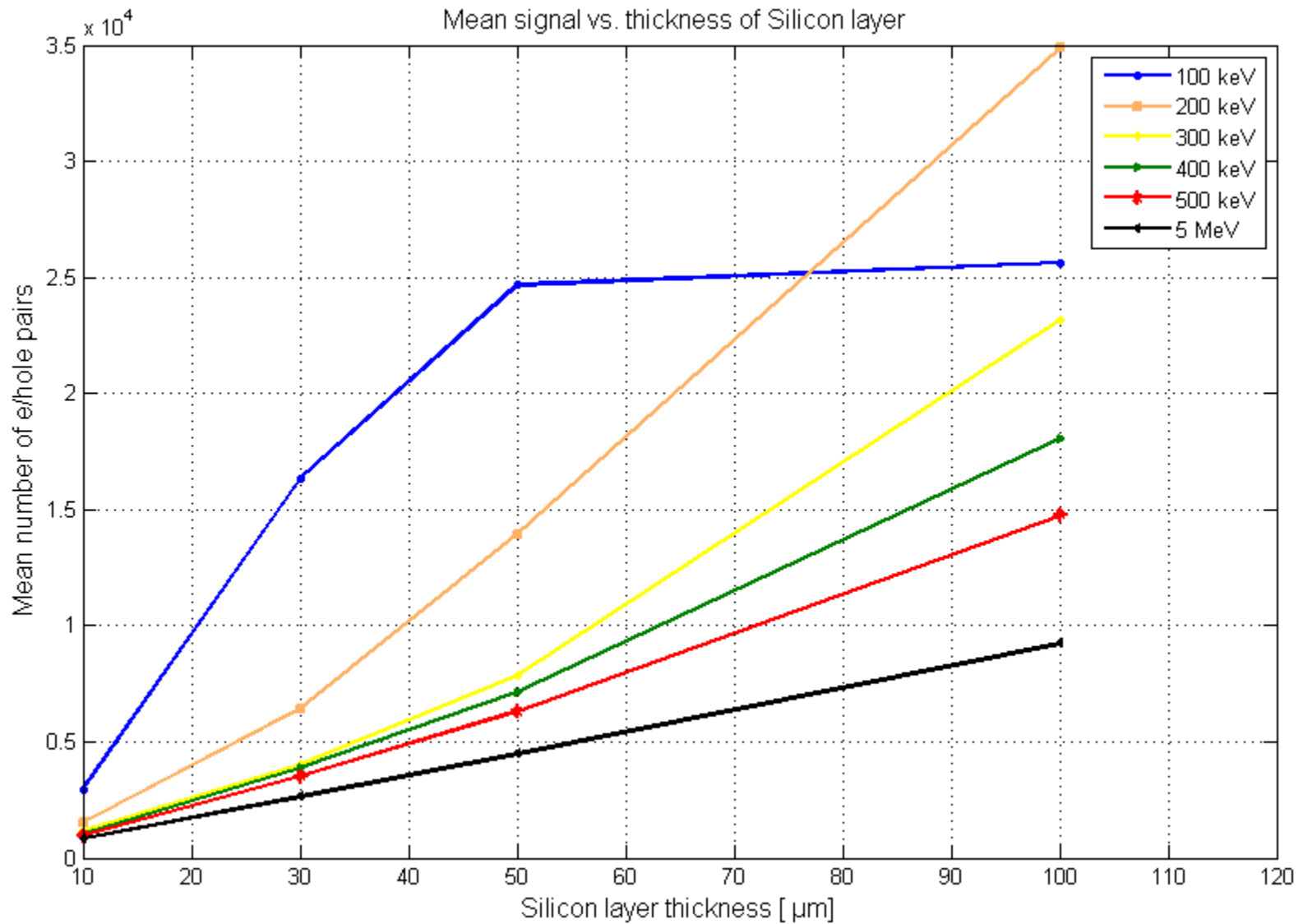


# Charge Handling



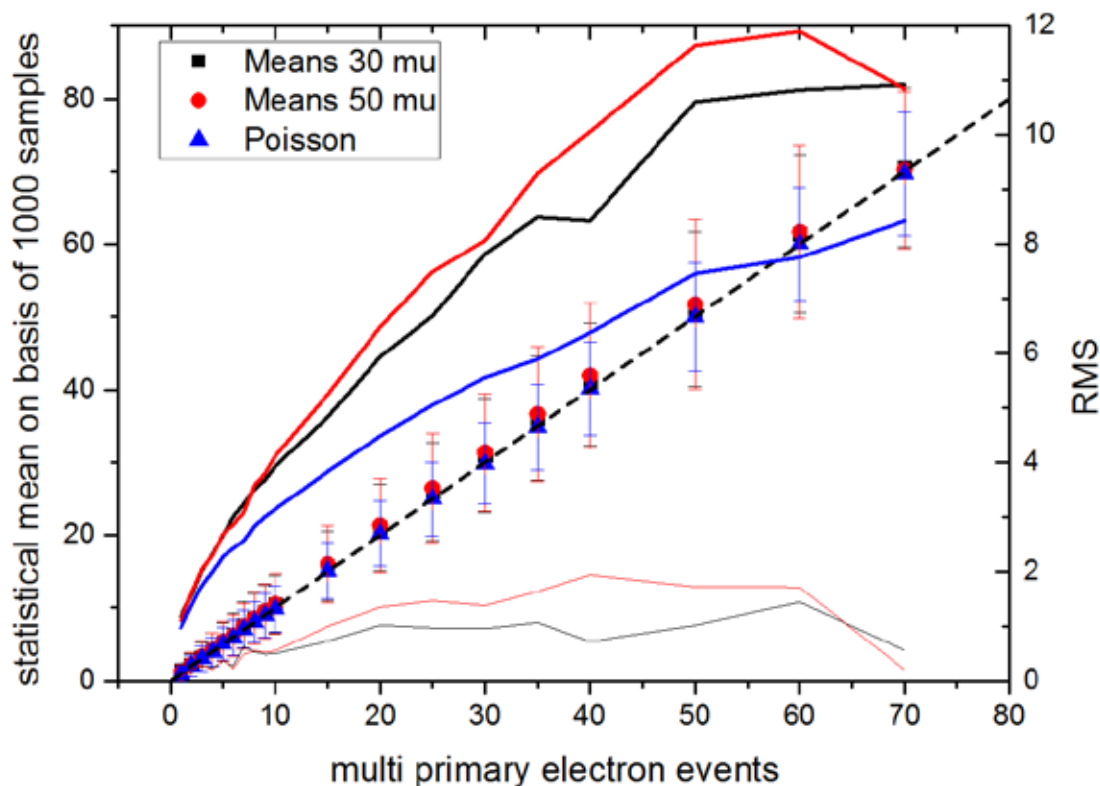
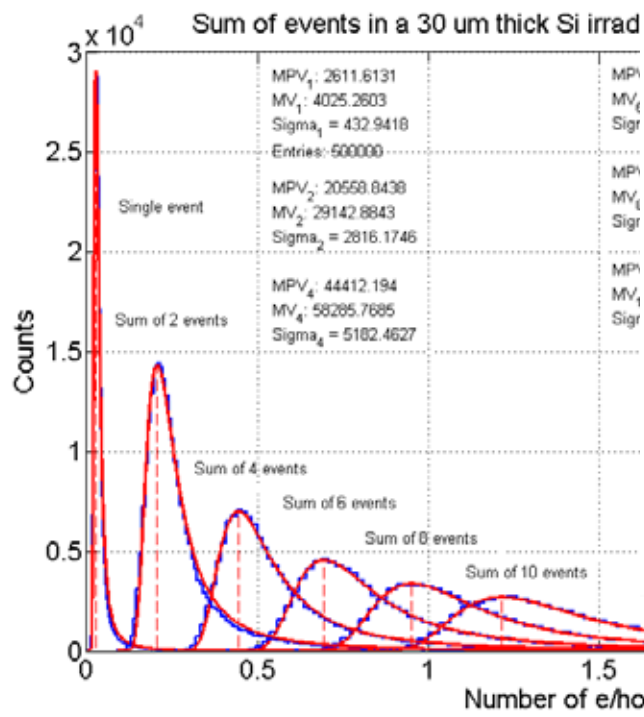
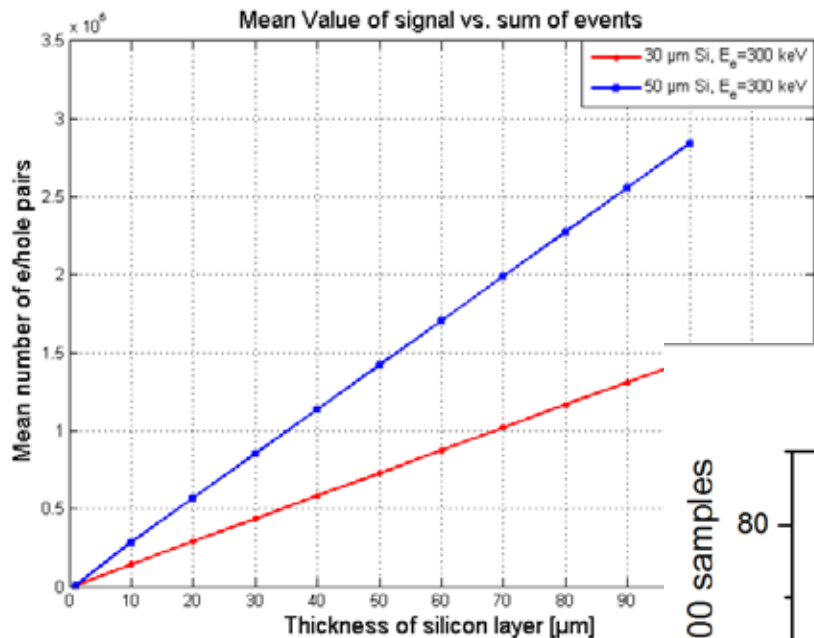
▶ On average: 1 e-h-pair/3.6 eV

▶ > 1M e-h pairs

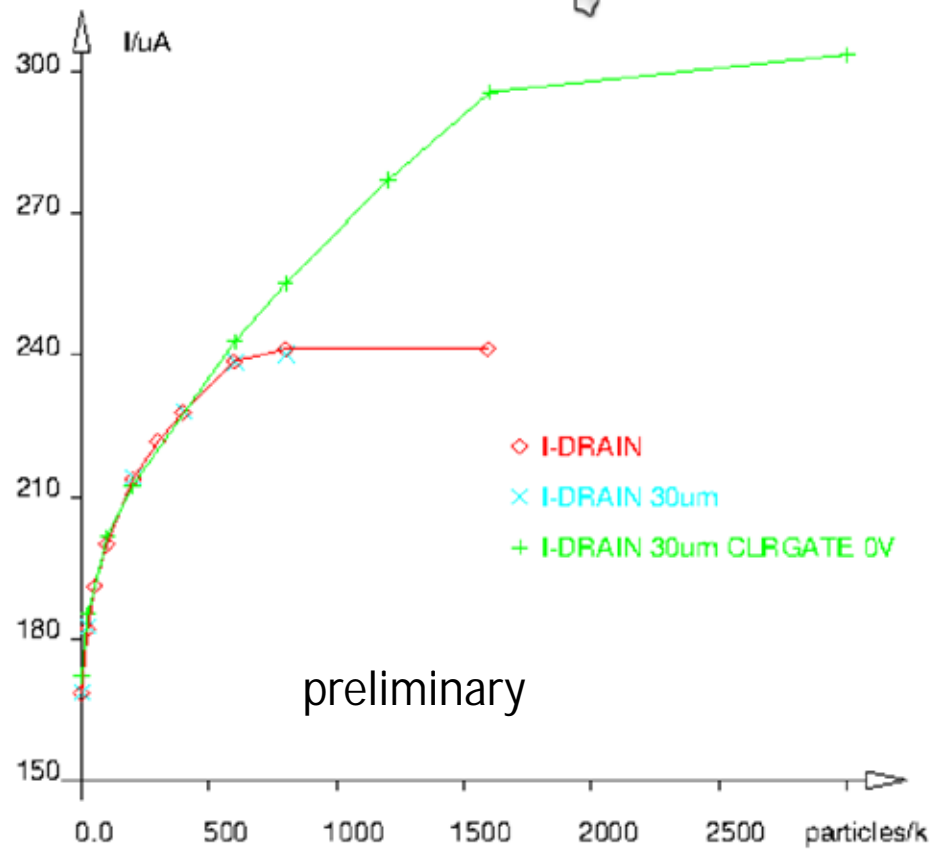
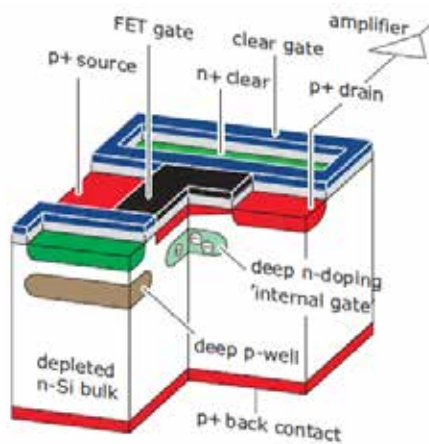


Low energy electrons generate more signal than high energy electrons  
Low energy electron  $\Rightarrow$  large scattering angles

# Charge Handling & Statistics



# Tayloring the response curves

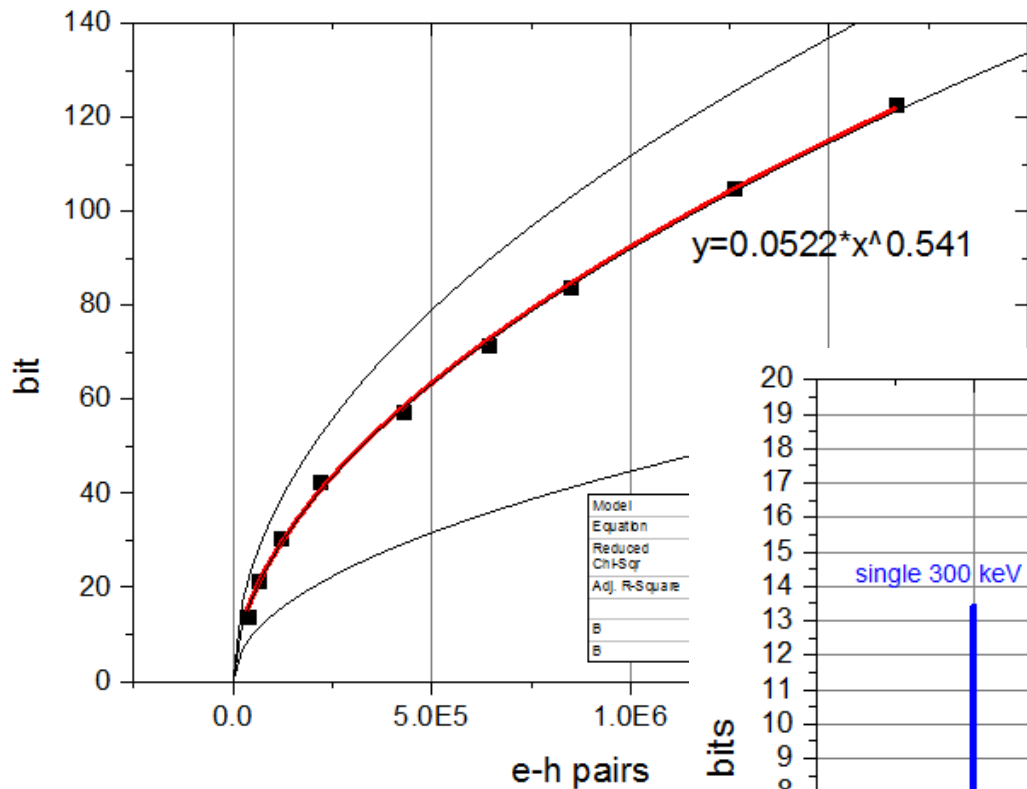


preliminary

BACK=-20V, CLRGATE1=2.5V, GATE=3V, SOURCE=0V, DRAIN=-5V,  
 DRIFT=-3V, CLEAR=2V, I DRAIN for different cloud sizes

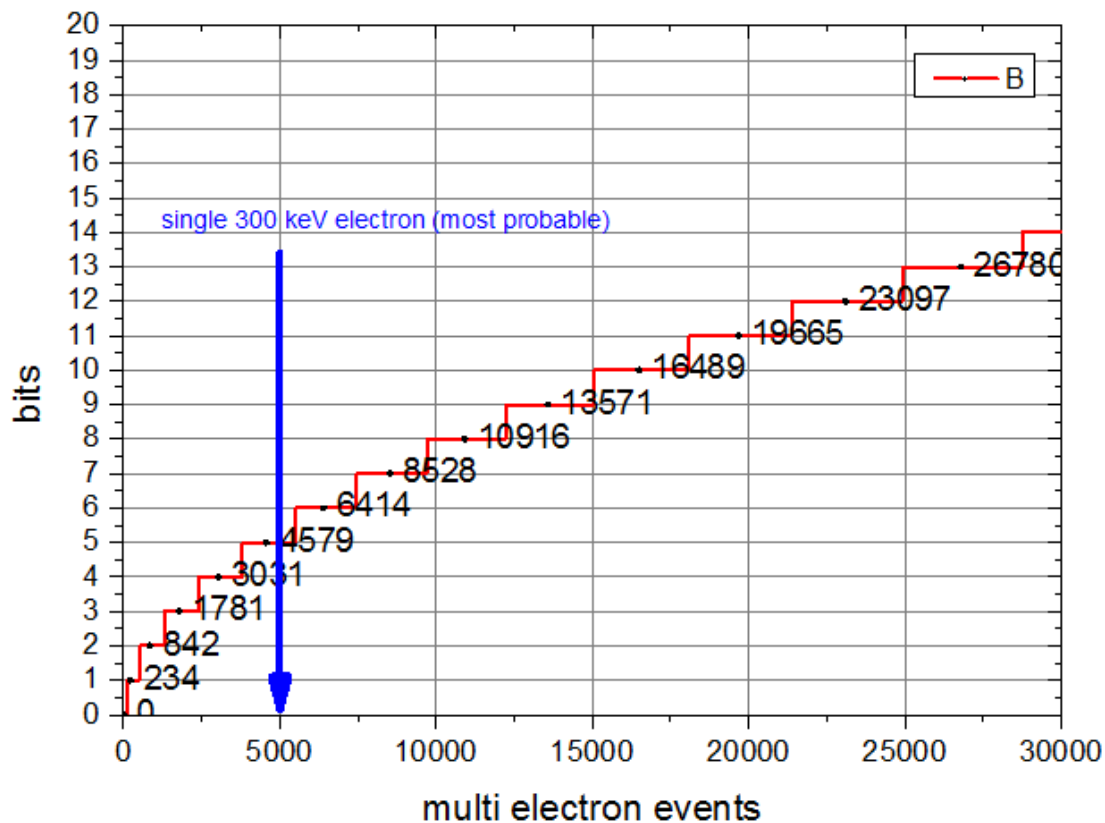
# Response curve

Edet with internal gate overflow



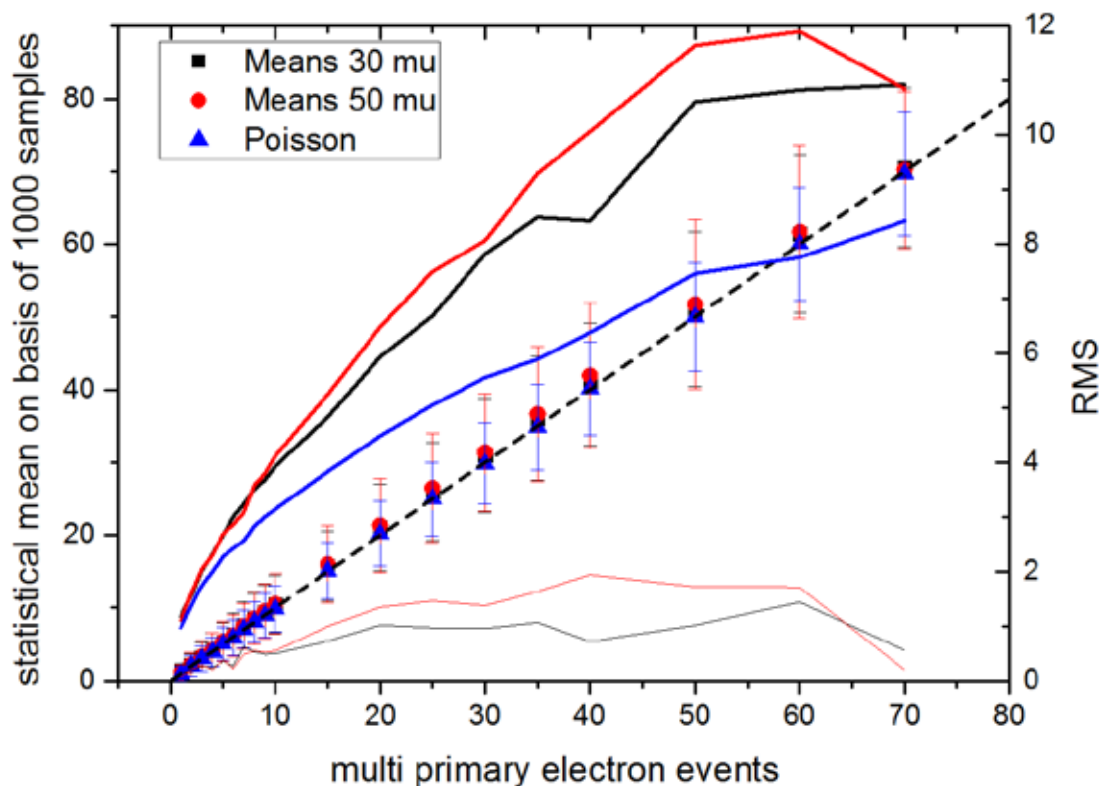
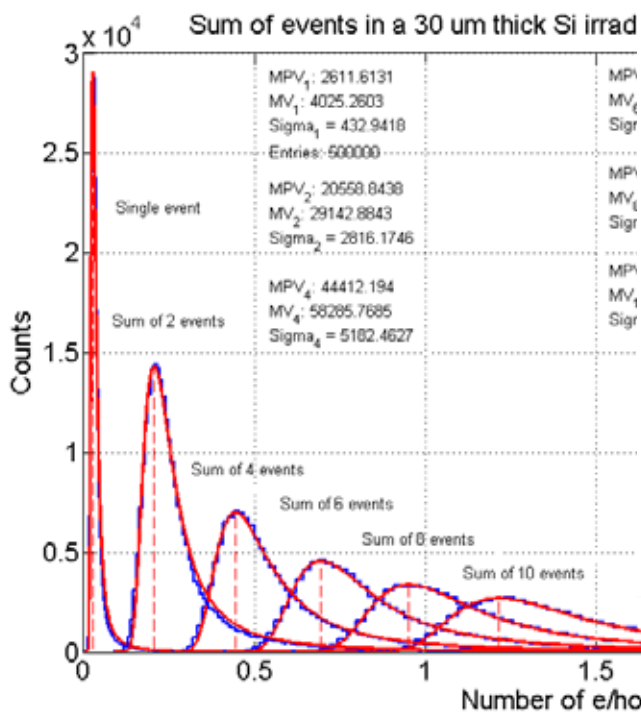
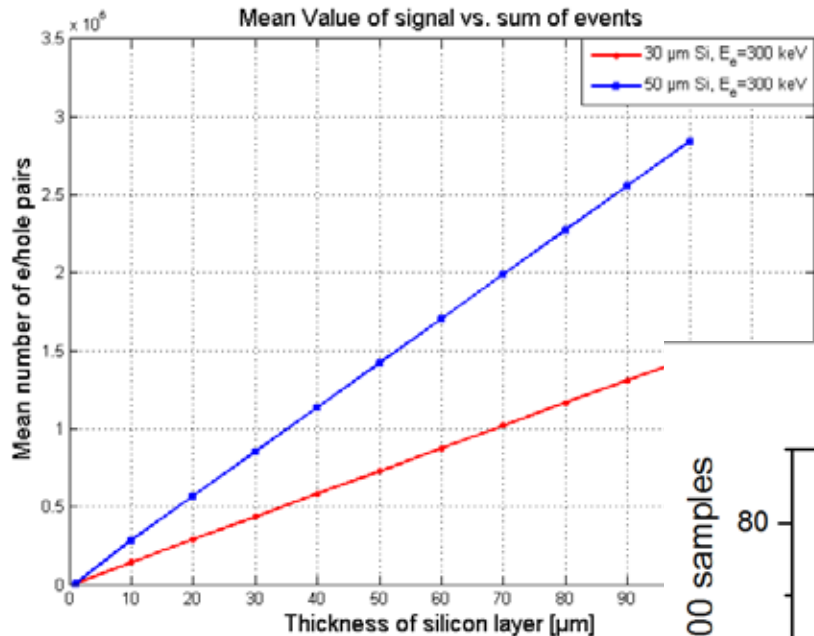
▶ reach high e-h numbers with 7 bit

▶ have some resolution below 1 primary electron (4 bit)



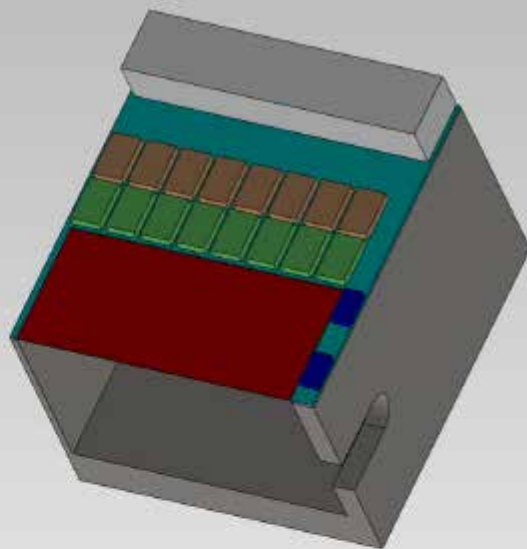
▶ Delta of 1 bit is below the Poisson noise (counting stat.)

# Charge Handling & Statistics



# Edet system (DH80k)

DEPFET direct hit



▶ direct electron detection

▶ 60 x 60 mm<sup>2</sup> active area

▶ 1000 x 1000 px (4 chips)

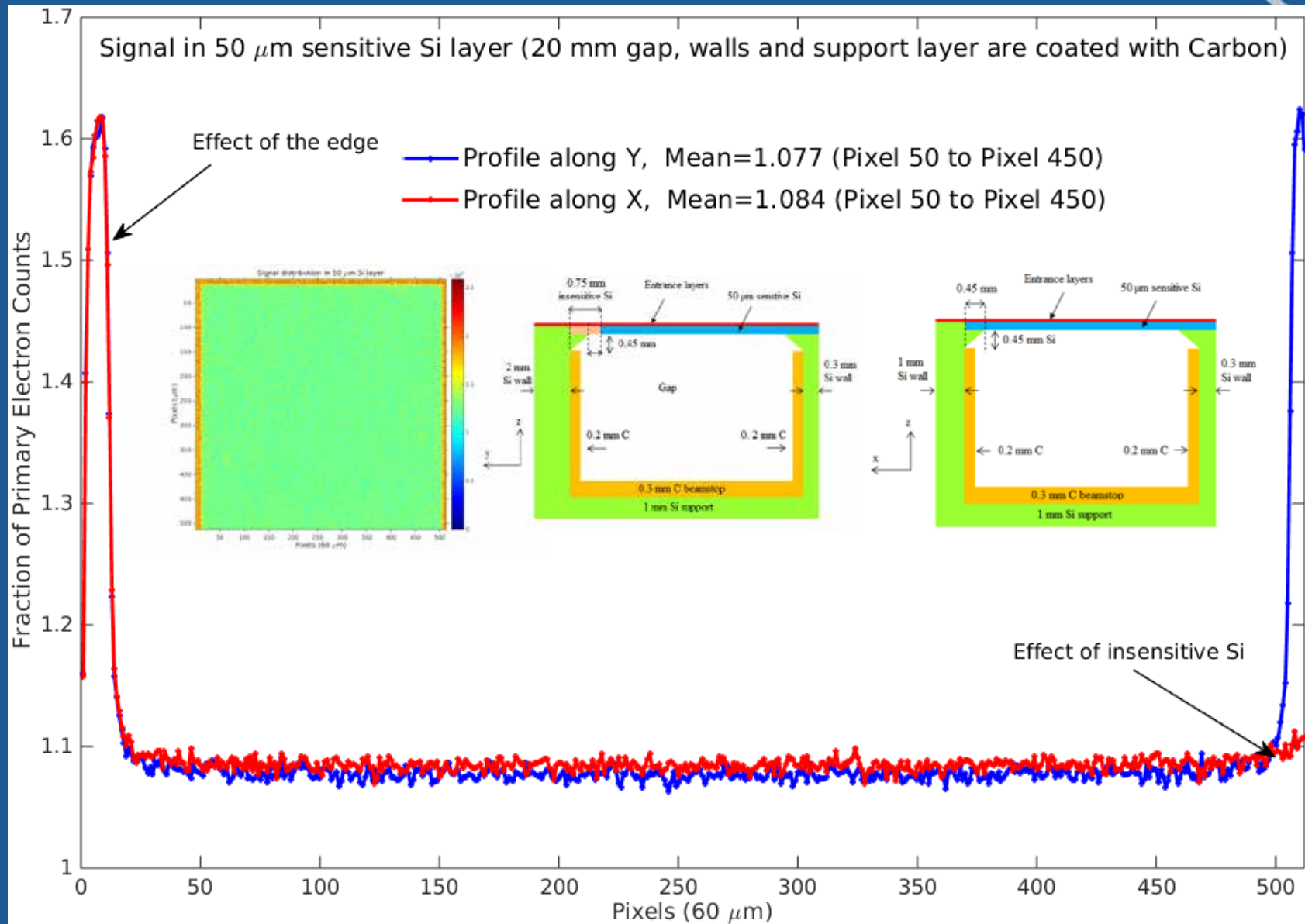
▶ pixel size: 60 x 60 μm<sup>2</sup>

▶ full frame readout 80kHz  
by 4-fold rolling shutter mode

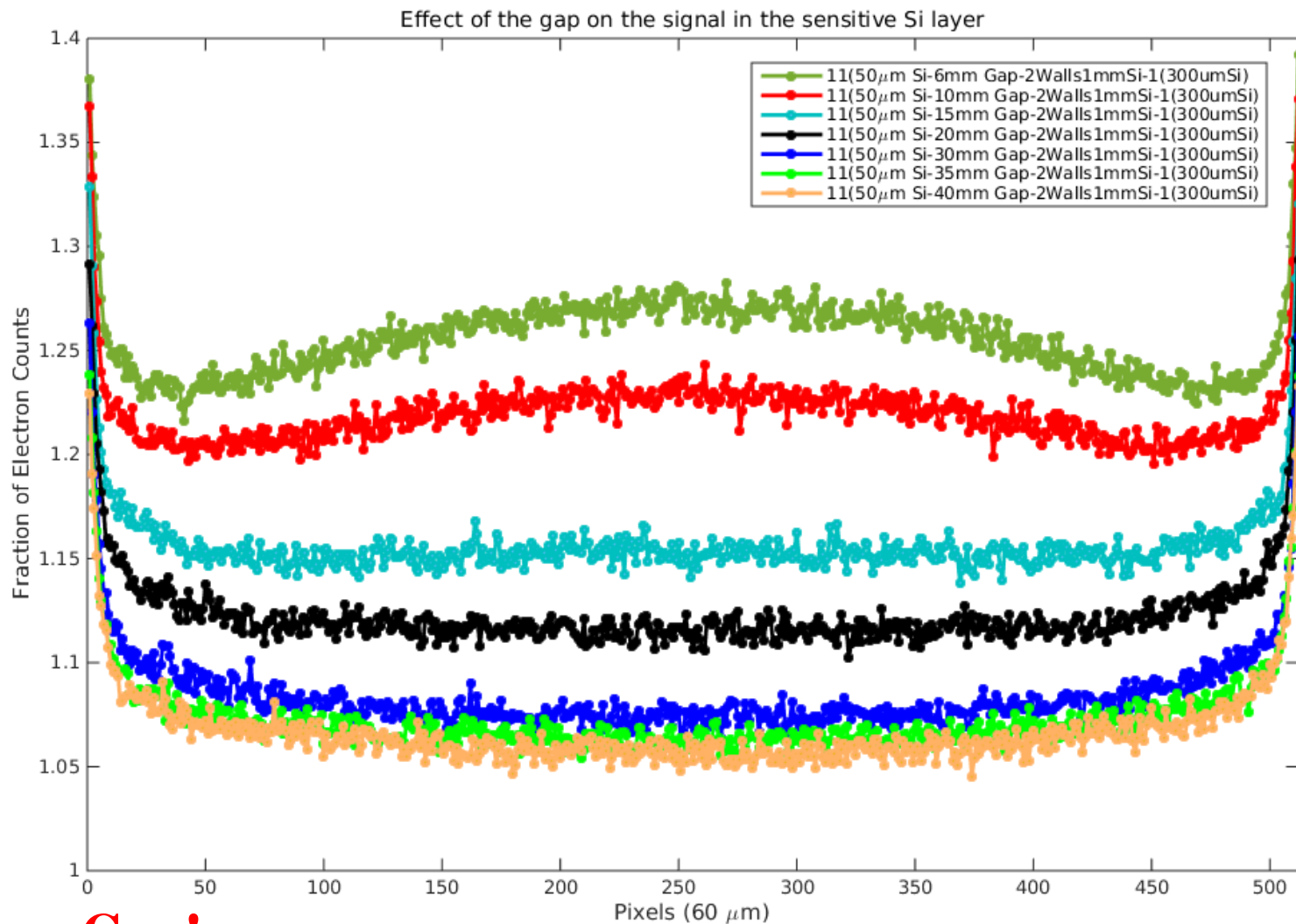
▶ dead joining region < 2 mm





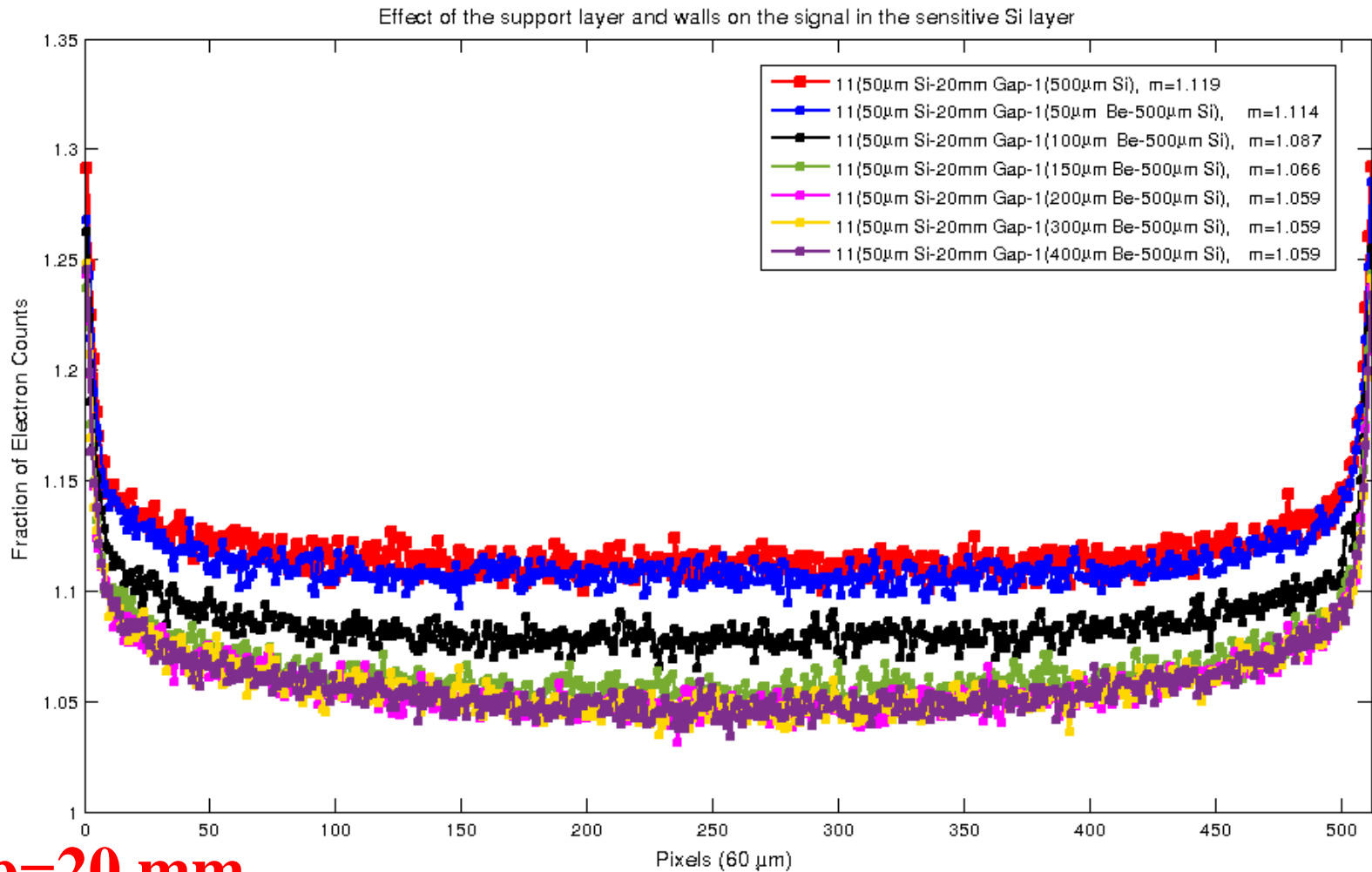


# RESULT1: 11(50 $\mu\text{m}$ Si)- Gap-2Walls1mmSi-1(300 $\mu\text{m}$ Si)



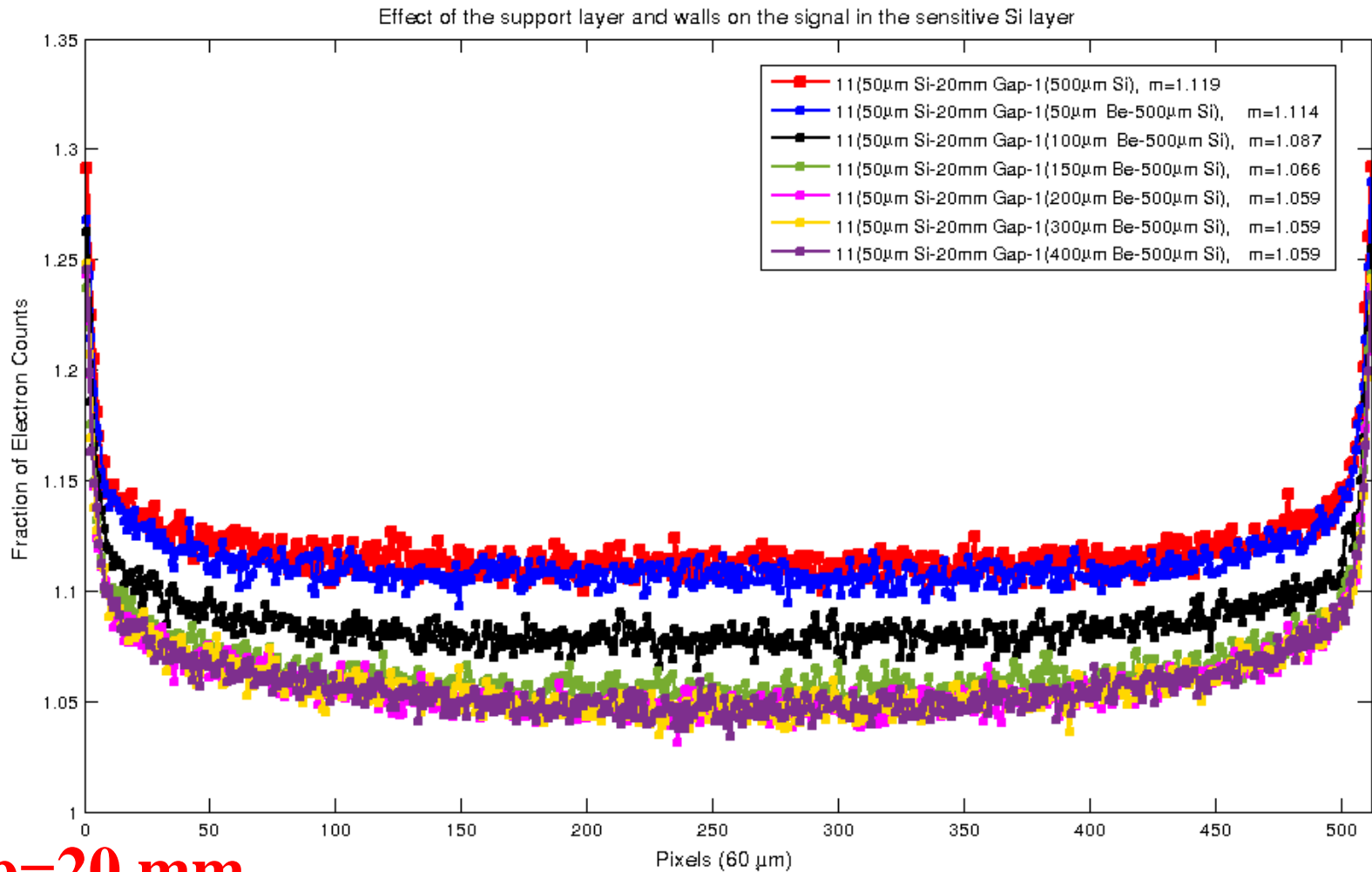
**Large Gap!**

# Effect of Be beamstop, walls and support layer on the signal



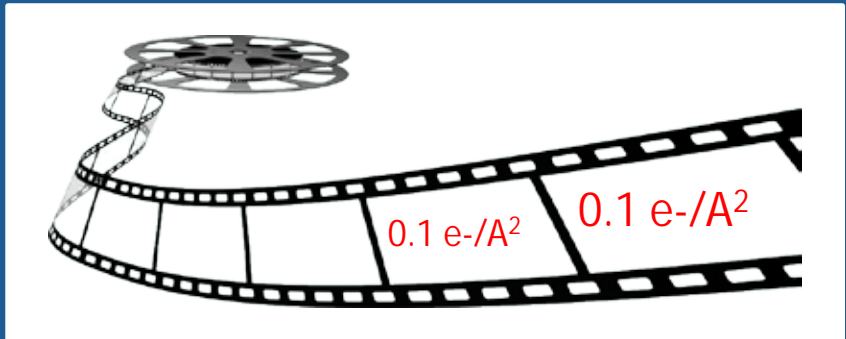
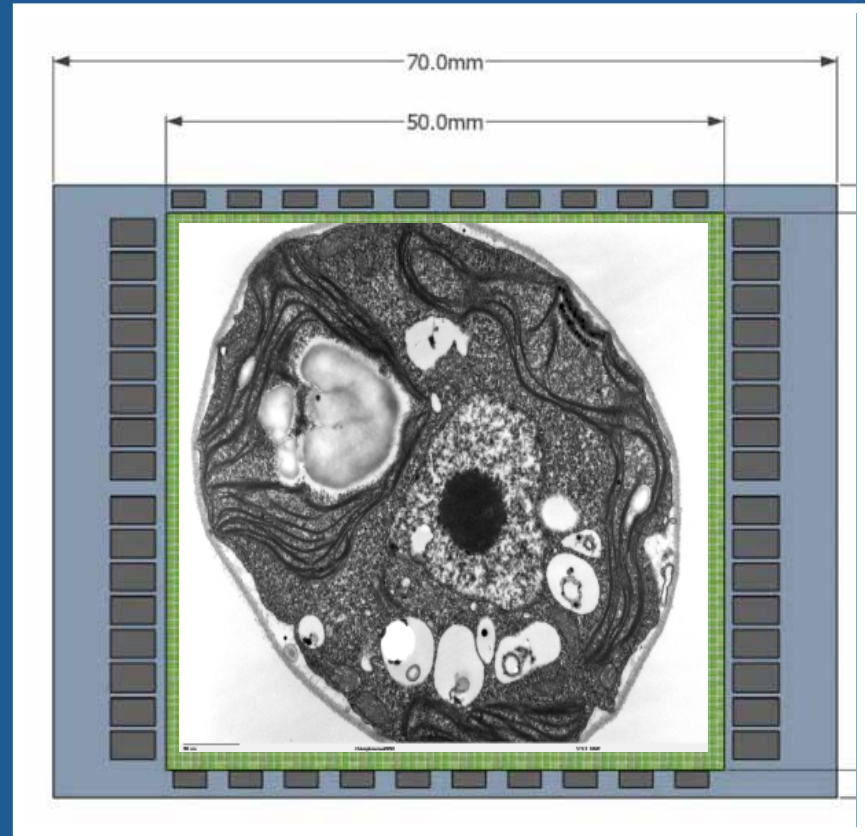
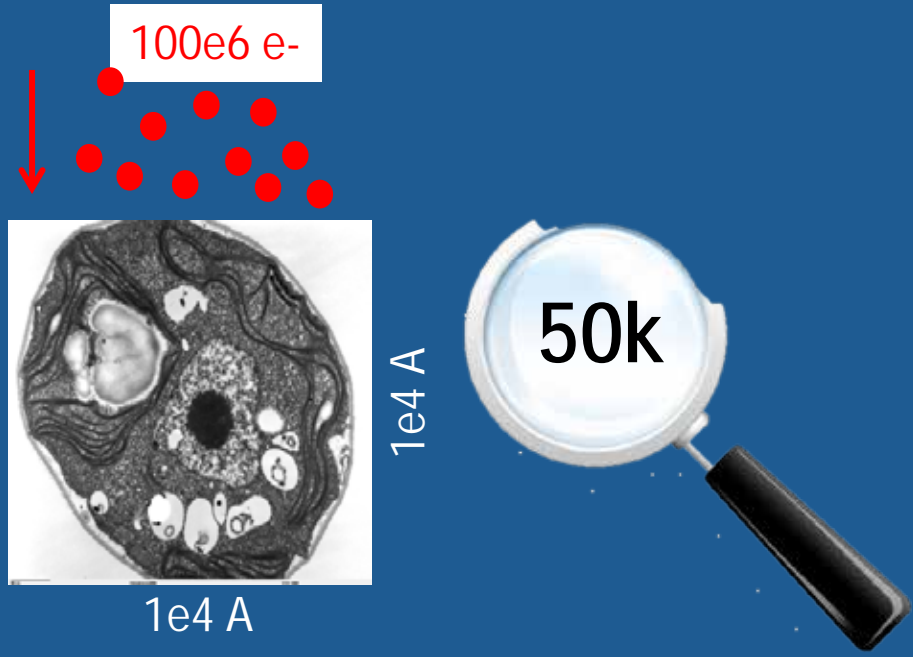
**Gap=20 mm**

# Effect of Be beamstop, walls and support layer on the signal



**Gap=20 mm**

# TEM movie

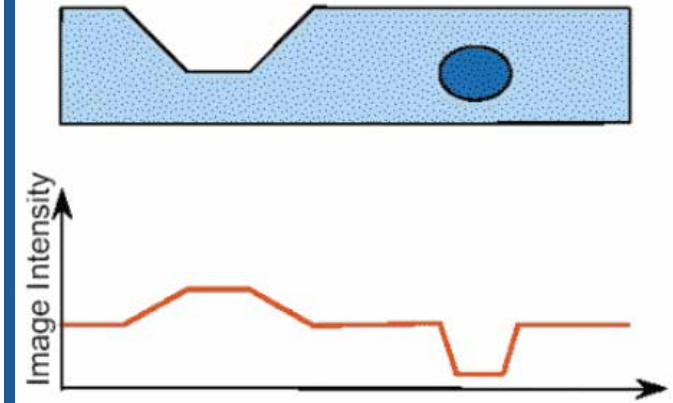
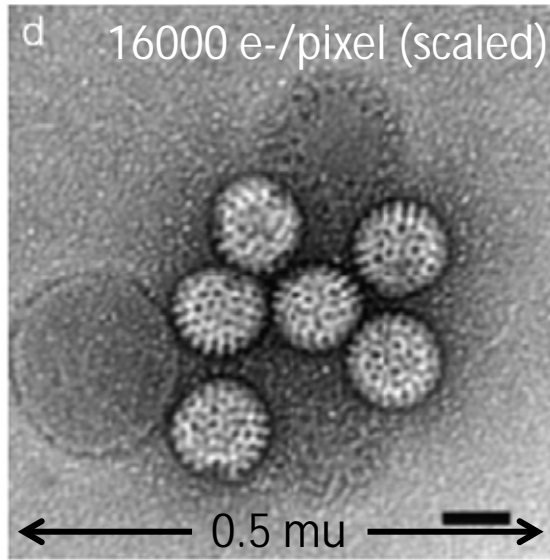
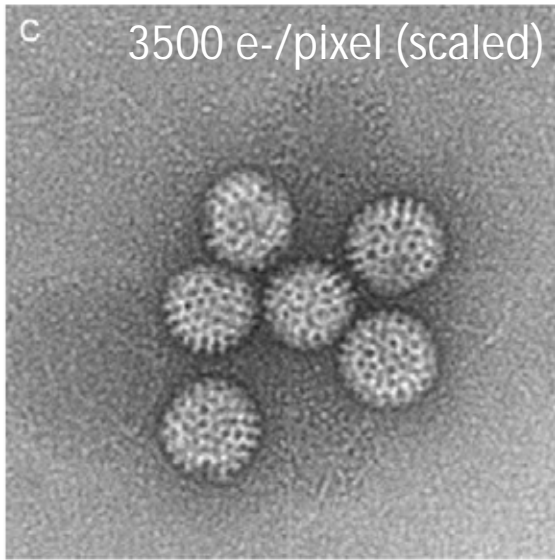
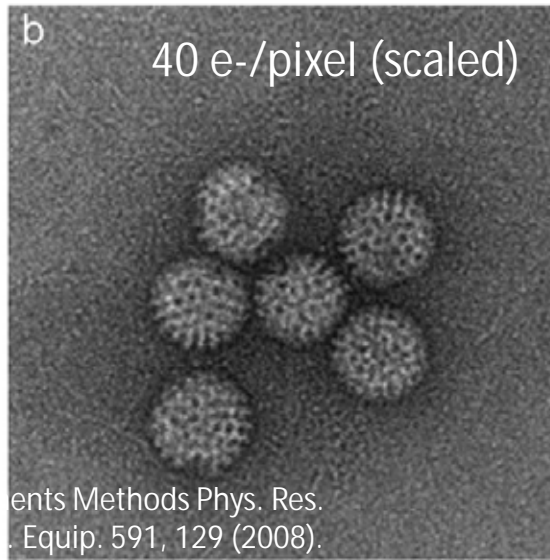
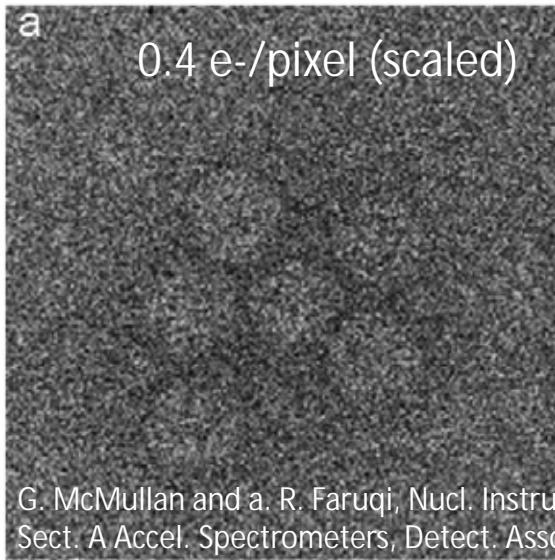


▶ for frames with 10M e- total, this would be 250M frames or 2.5 M movies

▶ 10 - 100 e- / pixel per single frame

▶ 10 - 100 e- / A<sup>2</sup> total area charge per 100 frame movie

# TEM movie



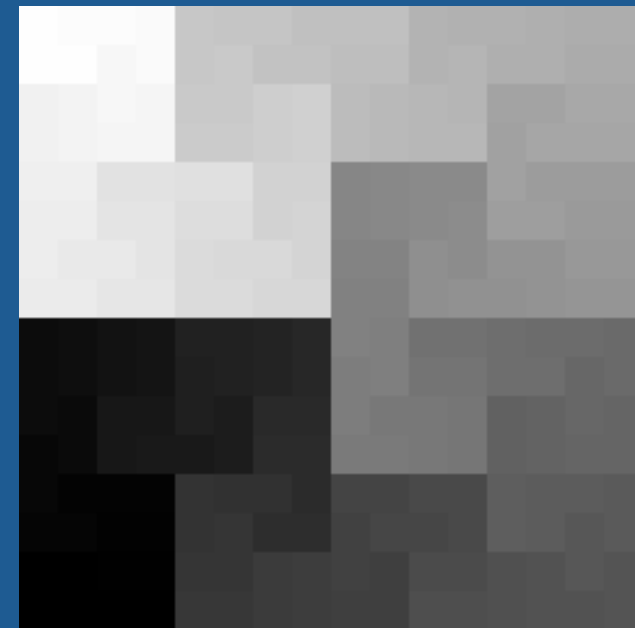
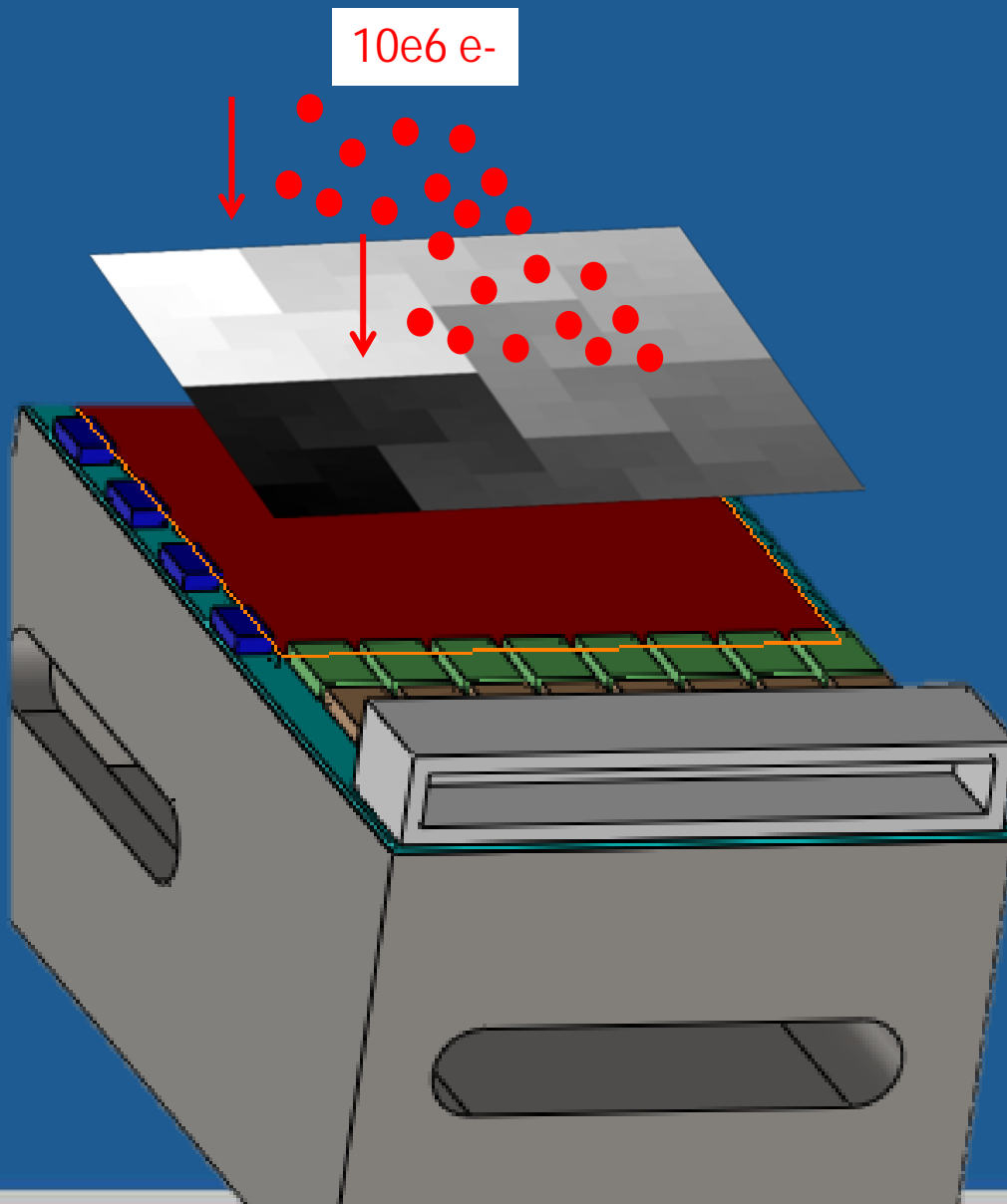
G. McMullan and a. R. Faruqi, Nucl. Instrum. Methods Phys. Res. Sect. A Accel. Spectrometers, Detect. Assoc. Equip. 591, 129 (2008).

▶ 150 primaries per dynamic frame

▶ 10 000 primaries per pixel for static exposure



# TEM movie

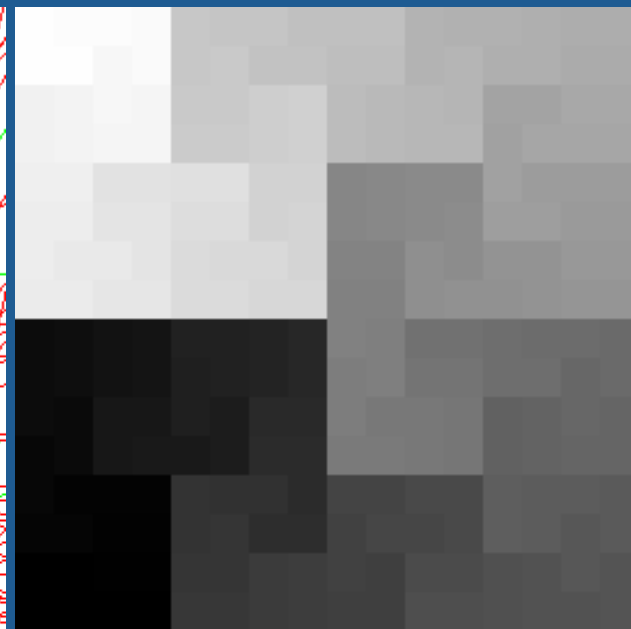
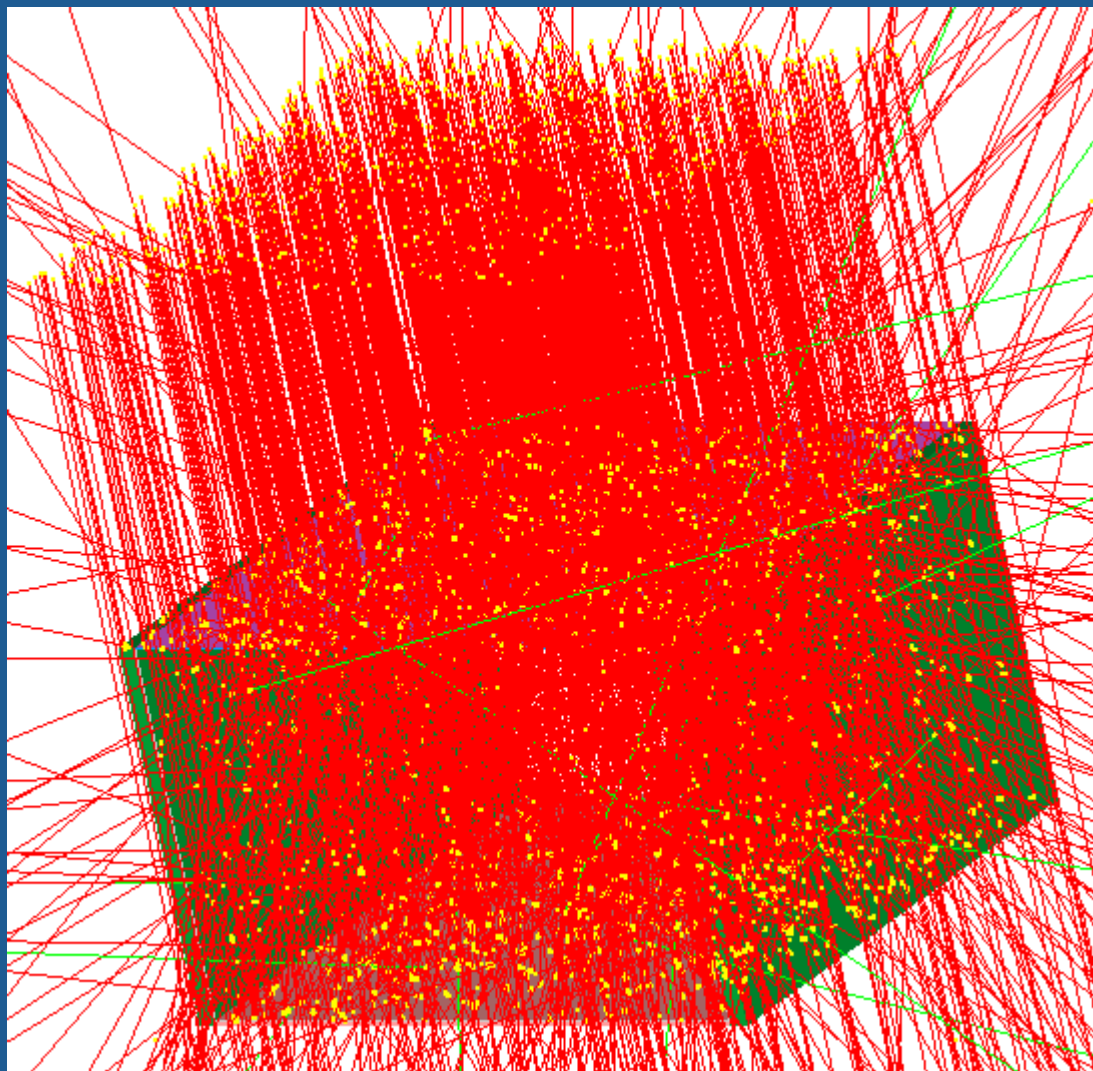


- ▶ 300 keV
- ▶ pitch black = 1000 A sample
- ▶ very white = 0 A sample
- ▶ 0..1000A in 256 steps



# TEM movie

100e-/px in white area



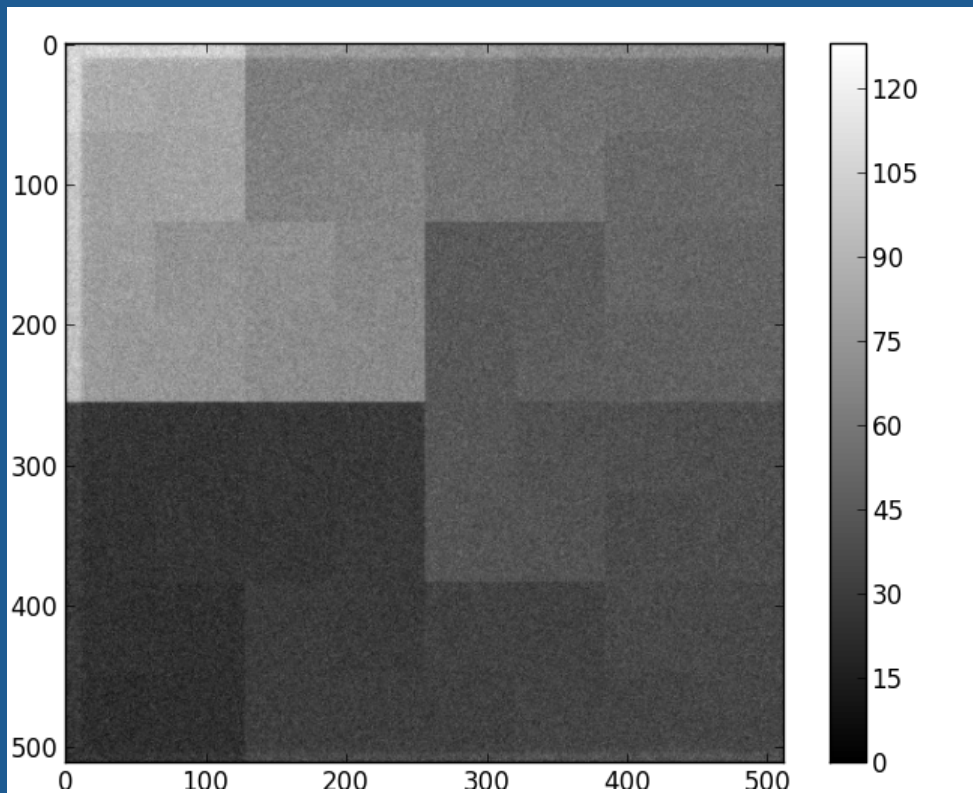
- ▶ 300 keV
- ▶ pitch black = 1000 A sample
- ▶ very white = 0 A sample
- ▶ 0..1000A in 256 steps





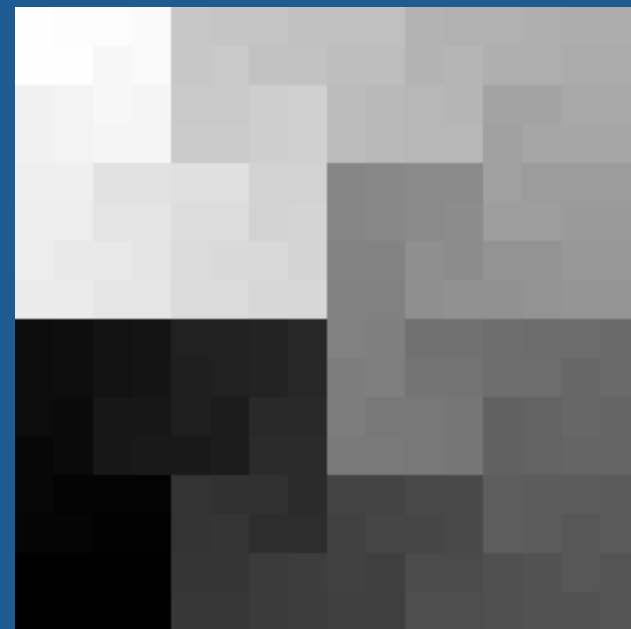
# TEM movie

100e-/px in white area



▶ bits read out

▶ Works nicely!!!



▶ 300 keV

▶ pitch black = 1000 A sample

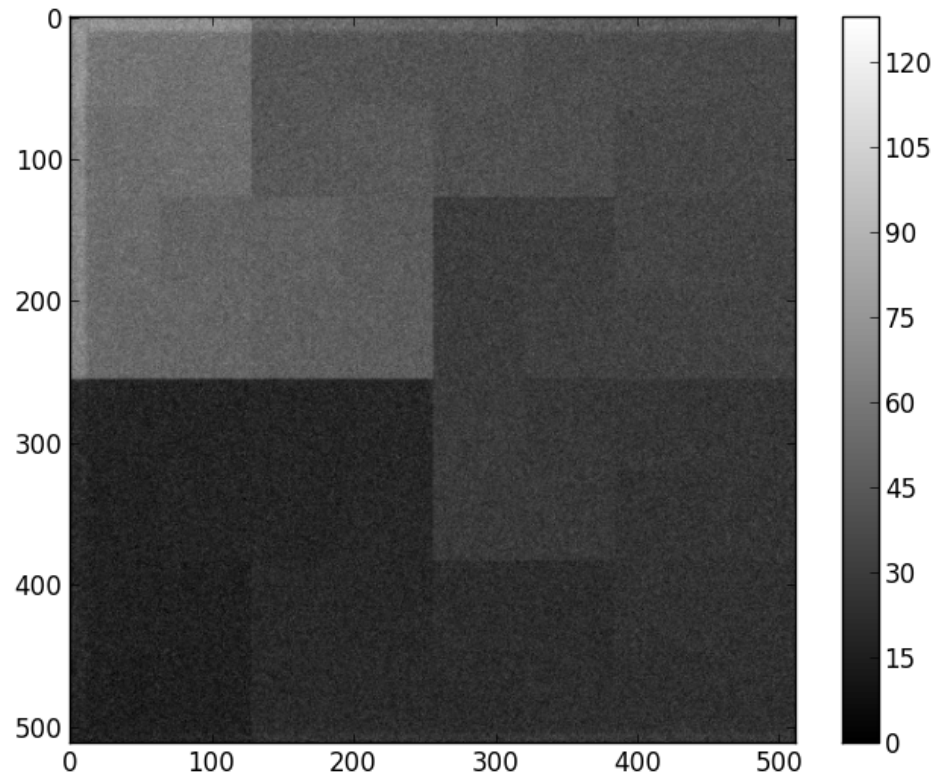
▶ very white = 0 A sample

▶ 0..1000A in 256 steps



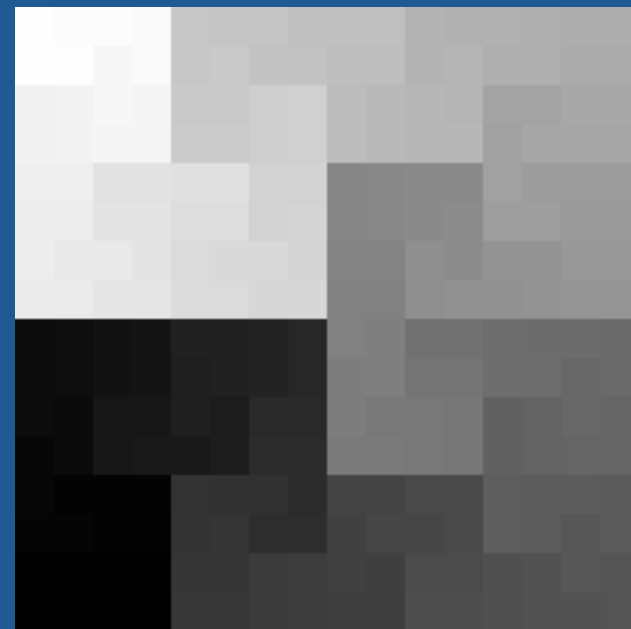
# TEM movie

50e-/px in white area



▶ bits read out

▶ Works nicely!!!



▶ 300 keV

▶ pitch black = 1000 A sample

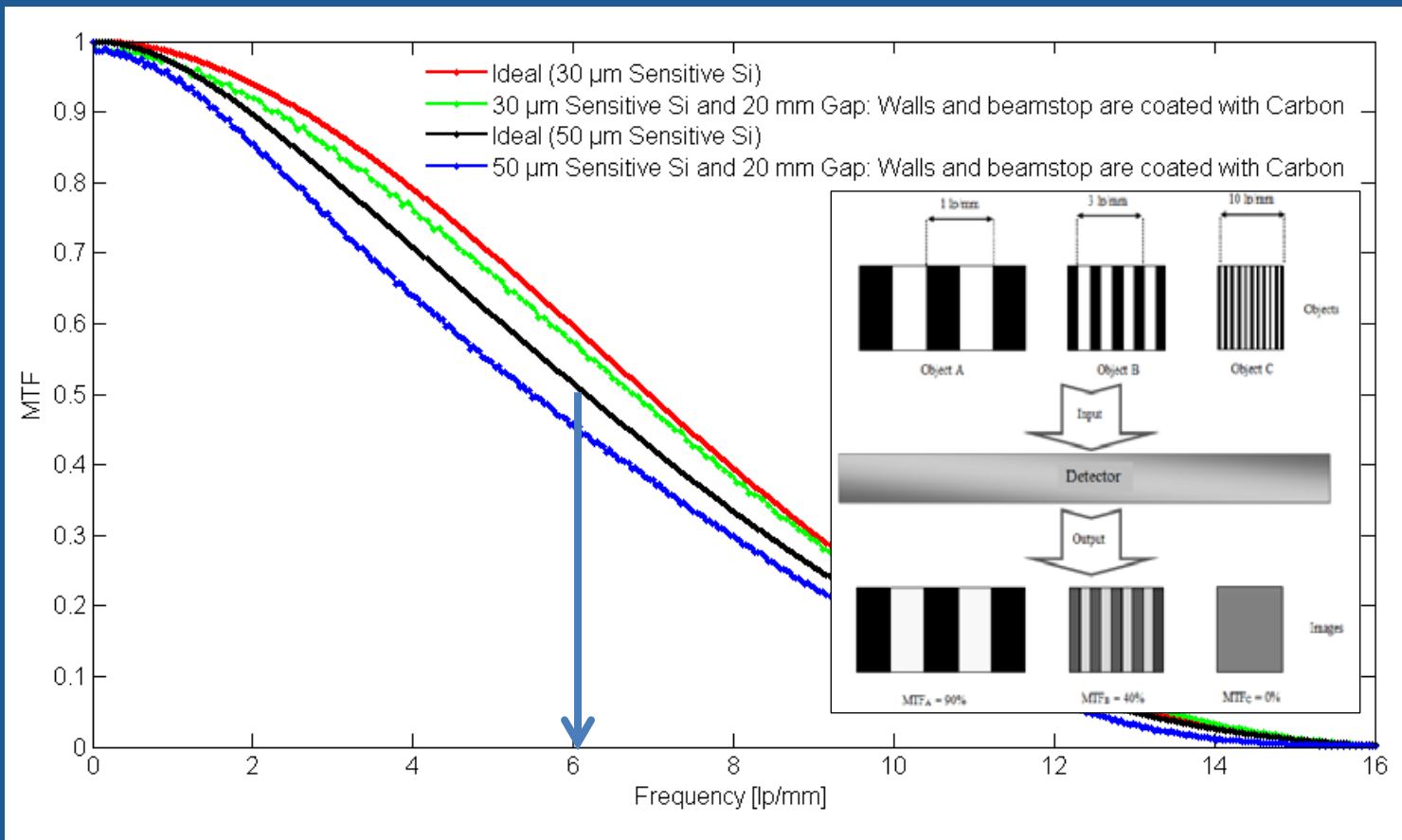
▶ very white = 0 A sample

▶ 0..1000A in 256 steps



# Some spatial investigations

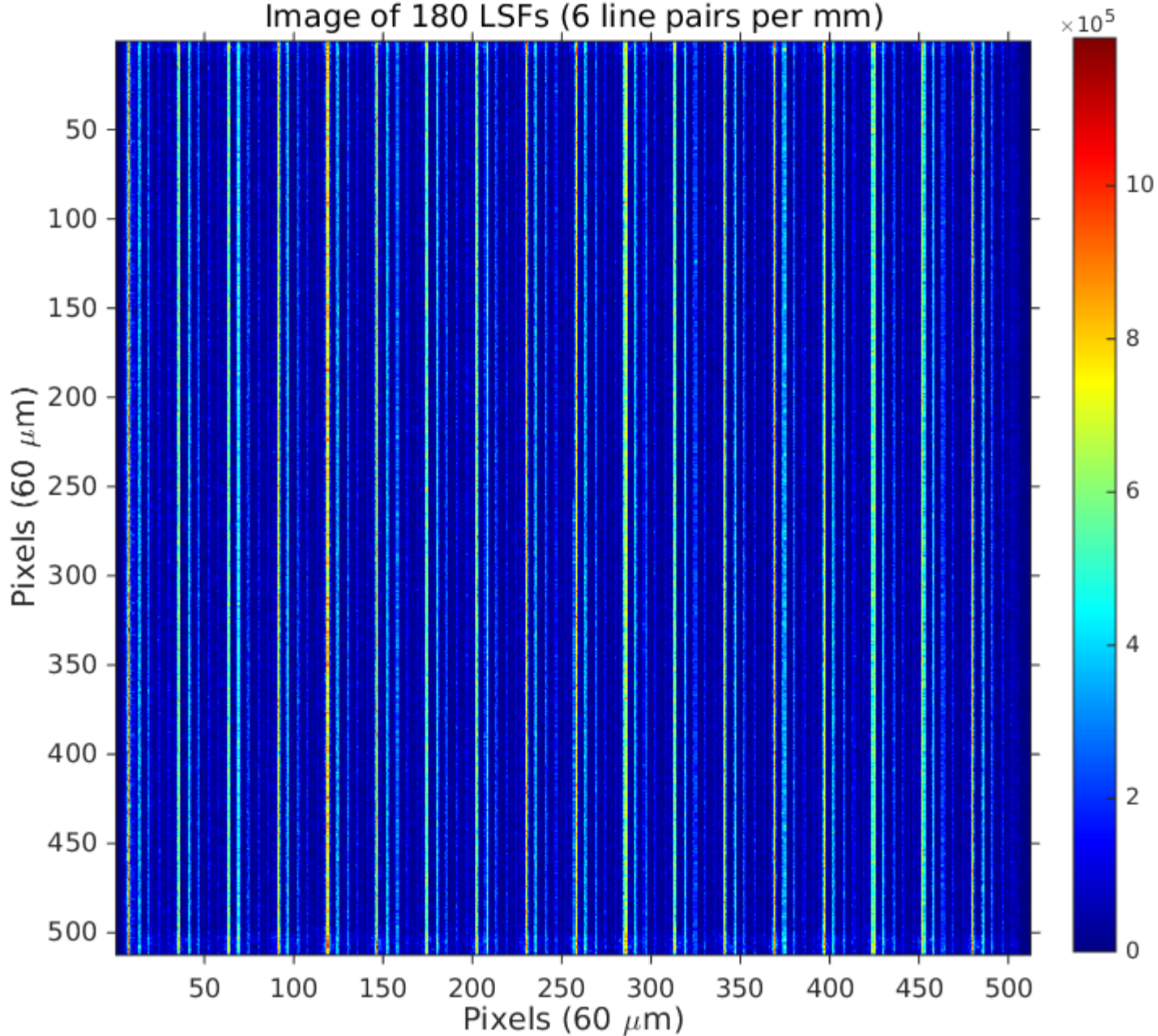
MTF (modulation transfer function)

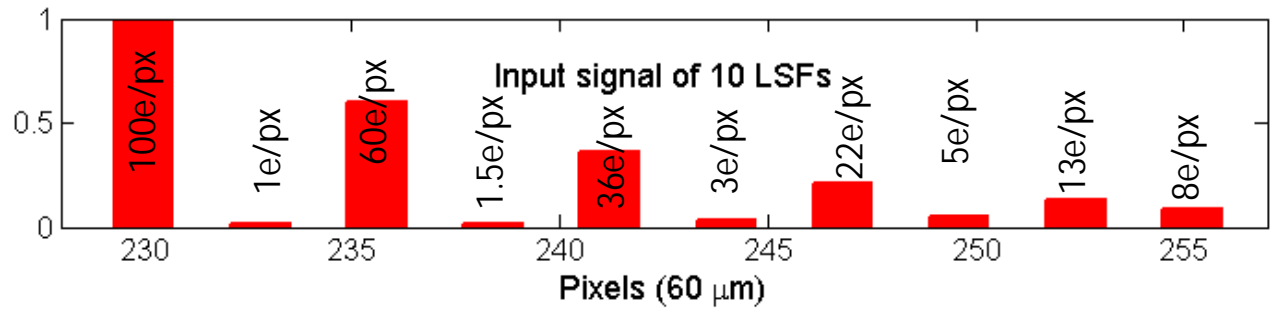
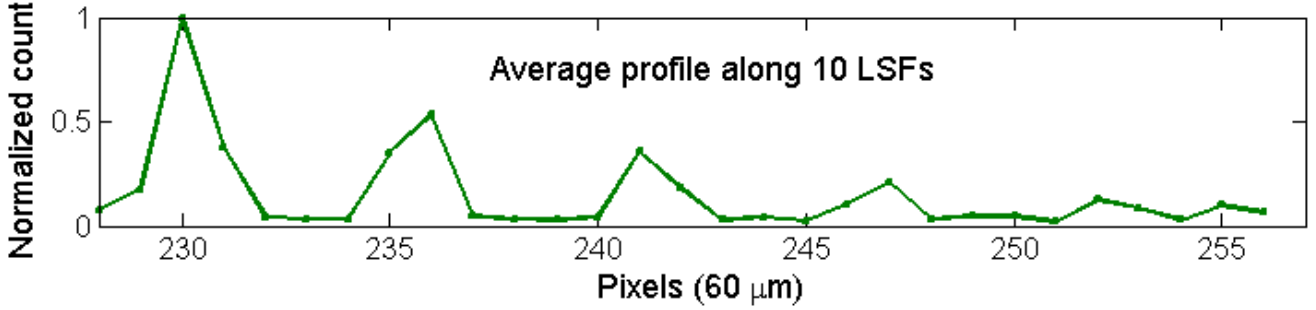
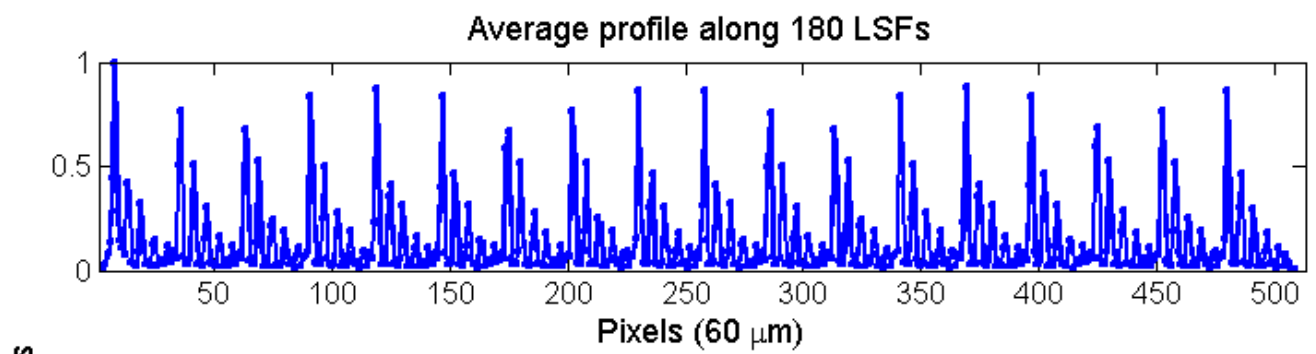
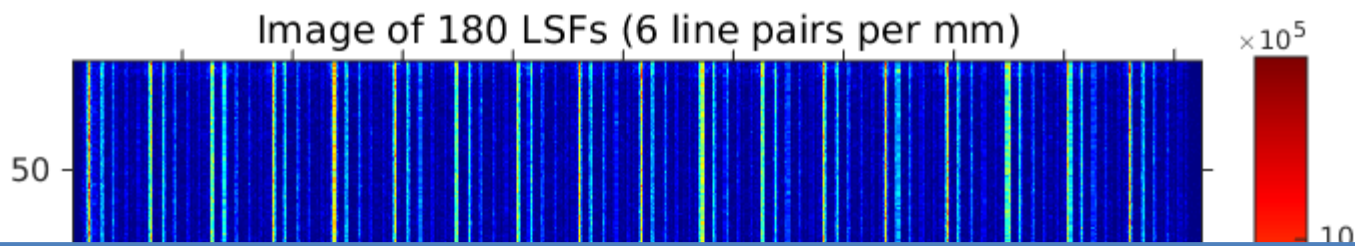


Spatial resolution ► Point Spread Function, Line Spread Function, Modulation Transfer Function: all inter-connected by operations like Differentiation, Fourier Transform etc.



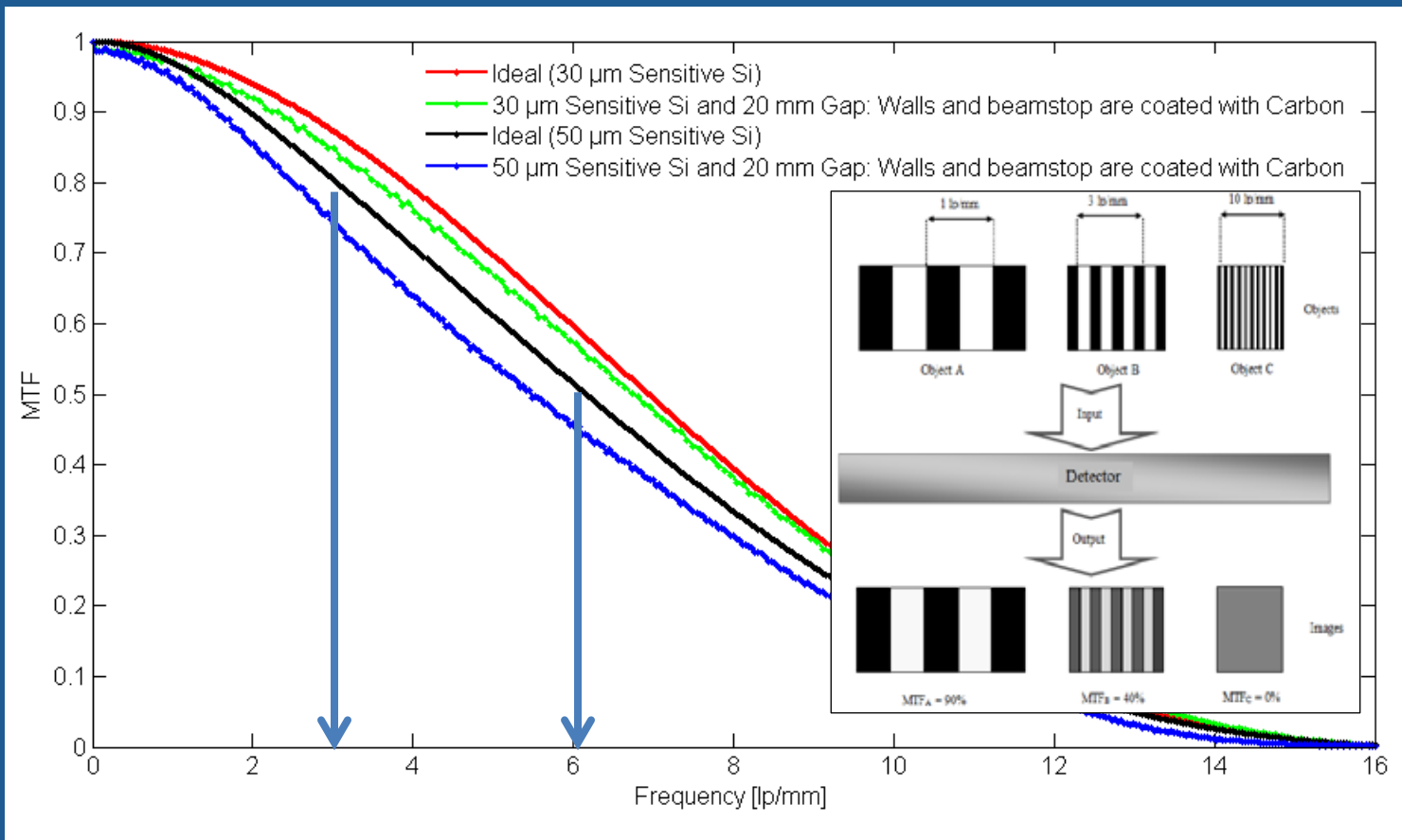
Image of 180 LSFs (6 line pairs per mm)





# Some spatial investigations

MTF (modulation transfer function)



Spatial resolution ► Point Spread Function, Line Spread Function, Modulation Transfer Function: all inter-connected by operations like Differentiation, Fourier Transform etc.

Image of 90 LSFs (3 line pairs per mm)

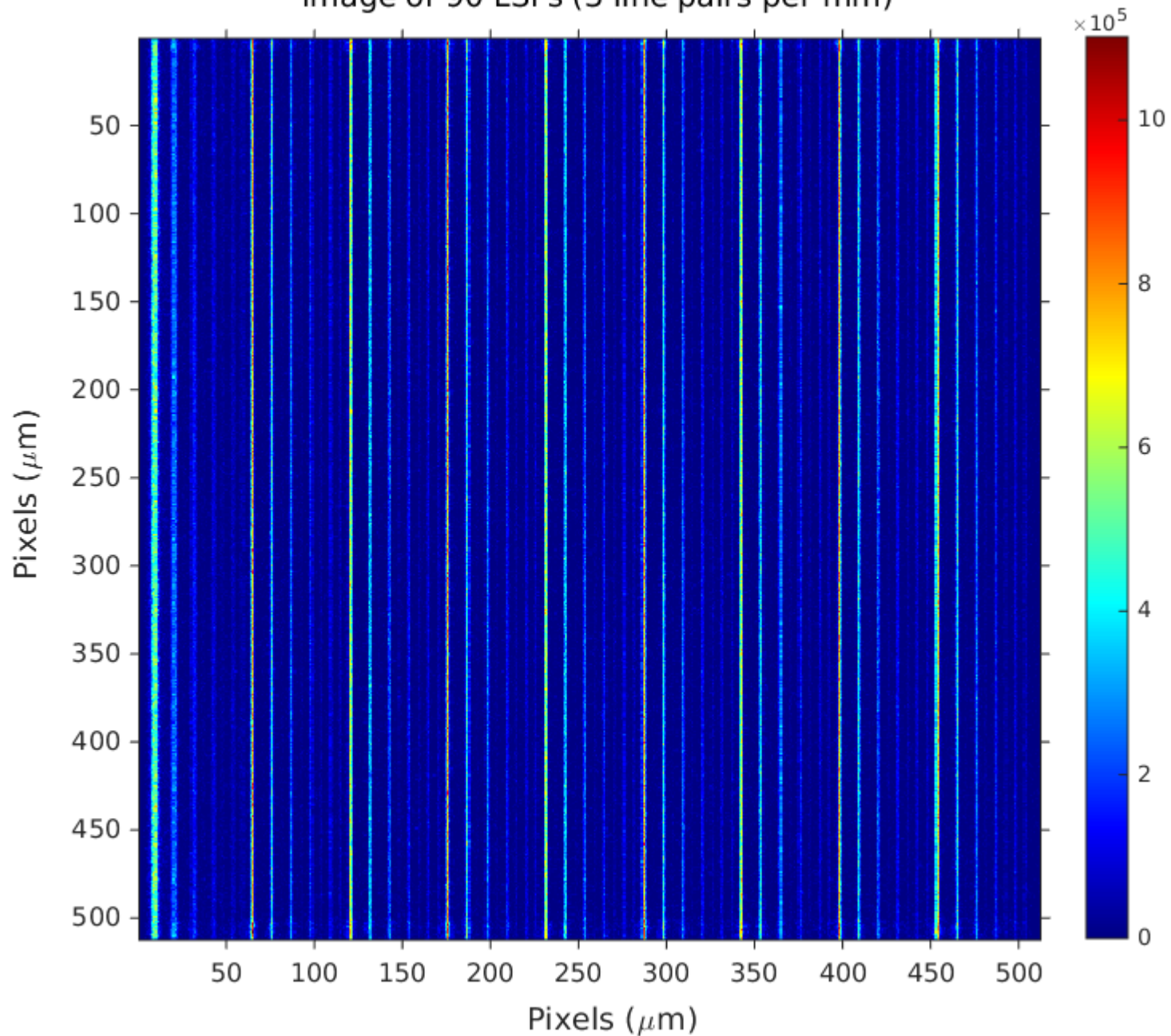
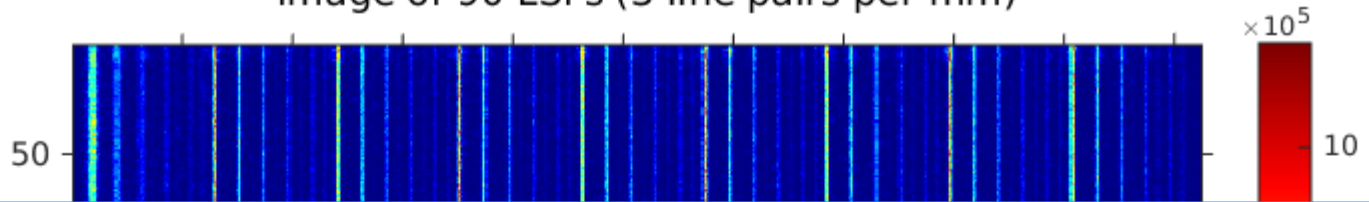
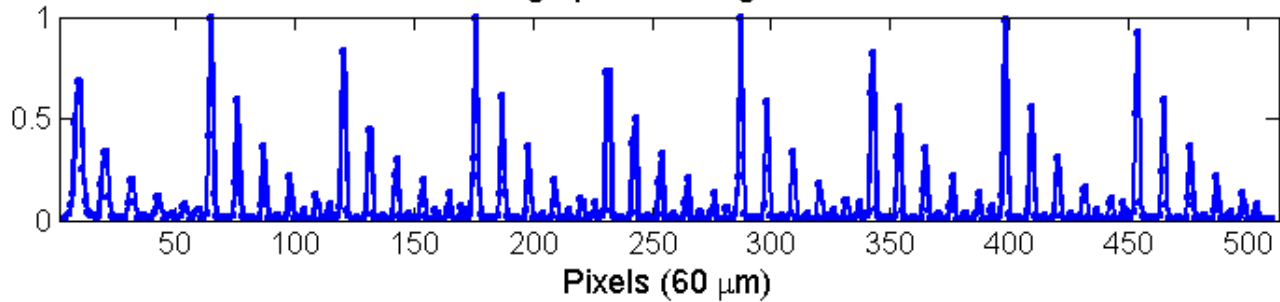


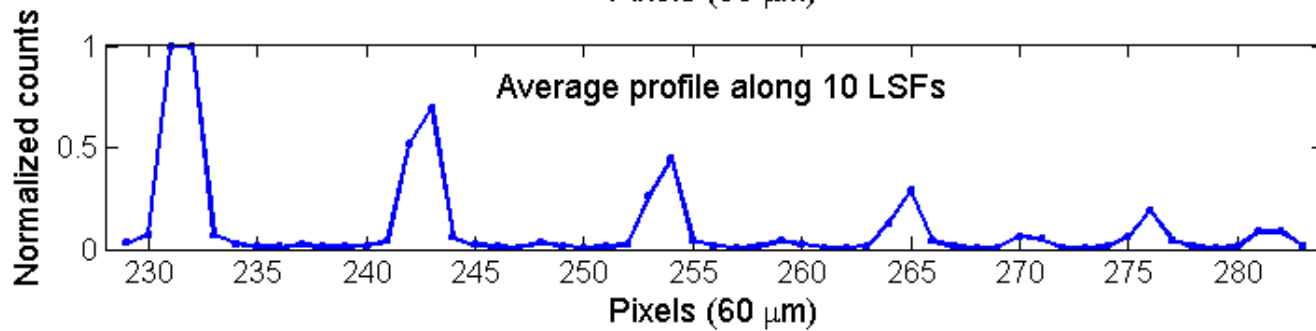
Image of 90 LSFs (3 line pairs per mm)



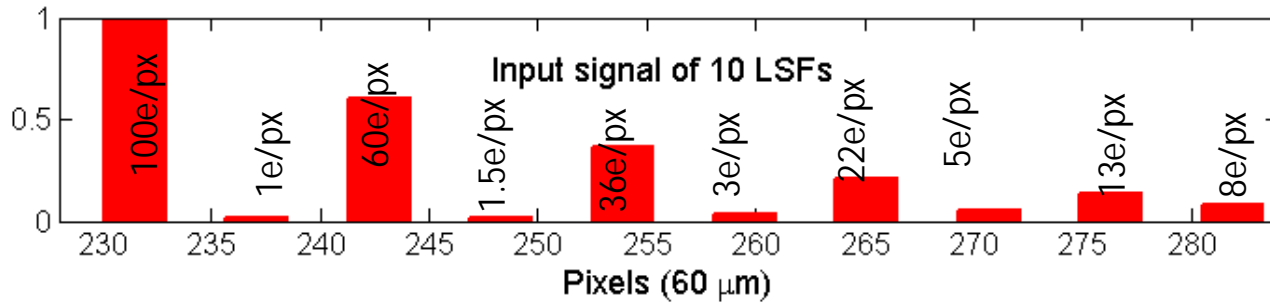
Average profile along 90 LSFs



Average profile along 10 LSFs



Input signal of 10 LSFs





# Timeline

revised



Last Milestone ▶ Sensor production of wafer has started at HLL (Oct. 2014)

▶ around 10 wafers are in processing (for 50 $\mu$ m and 30  $\mu$ m thick det.)

Next important step ▶ ASICs: DCD, Movie Chip

March 2016 ▶ DEPFET production start (DH1k) (Phase III)

March 2016 ▶ Completion of sensor production (DH80k) (Phase IV)

July 2017 ▶ Completion of DH80k detector system (Phase VI)

Dec. 2017 ▶ Completion of sensor production (DH1k) (Phase V)

2018 ▶ Completion of DH1k detector system (Phase VII)





Thank you !!!